SiT92211

10 Output, Differential, Ultra Low Jitter Buffer



Description

The SiT92211 is a 2.1 GHz, 10 output low-jitter clock fanout buffer, intended to be used in low jitter, high frequency clock/data distribution and level translation.

The buffer can choose a clock input from primary, secondary or crystal source. The primary and secondary clock sources can be single ended or fully differential. The selected clock can be distributed to two output drive banks A, B and one LVCMOS output.

The crystal input can support crystals from 8 MHz to 50 MHz. It can also support single ended clock.

The output drivers of each bank can be independently programmed to LVPECL, LVDS, HCSL or HIZ mode. The LVCMOS clock output is synchronized to selected clock and can be enabled or disabled in a glitch free manner.

The SiT92211 operates from a 3.3 V/2.5 V core supply and 3 independent 3.3 V/2.5 V output supplies. LVCMOS output driver can be operated at 1.8 V

Features

- Additive jitter performance of 55 fs RMS.
- 3:1 input clock selection
- Two universal clock inputs can operate up to 2.1 GHz and accept LVPECL, LVDS, LVCMOS, CML(ac-coupled only), HCSL, SSTL or single ended clocks
- One crystal input which can support crystals in the frequency range of 8 MHz to 50 MHz or it can accept single ended input clock.
- Two output driver banks A and B which can be programmed independently to LVPECL, LVDS, HCSL or HIZ mode.
- Typical output skew between clock outputs is 30 ps
- Level translation with core supply voltage of 3.3 V/2.5 V and 3.3 V/2.5 V output supply for differential output drivers.
- 3.3 V/2.5 V/1.8 V operation for the single LVCMOS output driver
- The SiT92211 buffer is pin controlled.
- High PSRR -70/-73 dBc for LVPECL/LVDS modes
- SiT92211 buffer is available in a 48-pin,
- 7mm x 7mm QFN package.
- Support PCI-e Gen1 to Gen5





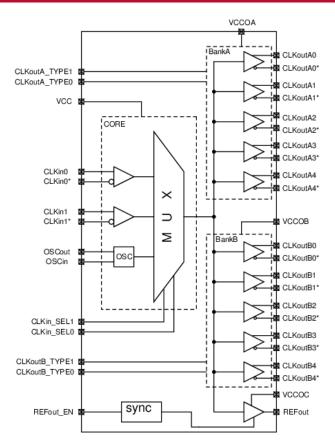


Figure 1. SiT92211 Block Diagram

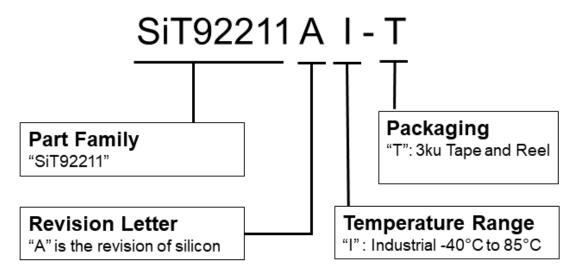


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Ordering Information





Electrical Characteristics

Table 1. Absolute Maximum Ratings

Parameters	Symbol	Min	Тур	Max	Units
Core supply voltage, Analog Input	V _{cc}	-0.3		3.6	V
Output bank supply voltage	V _{cco}	-0.3		3.6	V
Input voltage, All Inputs, except OSC _{IN}	V _{IN}	-0.3		3.6	V
OSC _{IN}	V _{IN}	-0.5		1.8	V
Storage temperature	Ts	-55		150	°C
Moisture Saturation Level	MSL		3		

Notes:

- Exceeding maximum ratings may shorten the useful life of the device.
- Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings
 only and functional operation of the device at these or at any other conditions beyond those indicated under the DC Electrical
 Characteristics is not implied. Exposure to Absolute-Maximum-Rated conditions for extended periods may affect device reliability or
 cause permanent device damage.

Table 2. Recommended Operating Conditions

Symbol	Min	Тур	Max	Units
V _{CC}	3.135	3.3	3.45	V
V _{CC}	2.375	2.5	2.625	V
V _{CCOA/B}	3.135	3.3	3.45	V
V _{CCOA/B}	2.375	2.5	2.625	V
V _{CCOA/B} ¹	1.71	1.8	1.89	V
V _{ccoc}	3.135	3.3	3.45	V
V _{ccoc}	2.375	2.5	2.625	V
V _{ccoc}	1.71	1.8	1.89	V
T _A	-40		85	°C
TJ			125	°C
	V _{CC} V _{CC} V _{CCOA/B} V _{CCOA/B} V _{CCOA/B} V _{CCOC} V _{CCOC} V _{CCOC} T _A	V _{CC} 3.135 V _{CC} 2.375 V _{CCOA/B} 3.135 V _{CCOA/B} 2.375 V _{CCOA/B} 1.71 V _{CCOC} 3.135 V _{CCOC} 2.375 V _{CCOC} 1.71 T _A -40	V _{CC} 3.135 3.3 V _{CC} 2.375 2.5 V _{CCOA/B} 3.135 3.3 V _{CCOA/B} 2.375 2.5 V _{CCOA/B} ¹ 1.71 1.8 V _{CCOC} 3.135 3.3 V _{CCOC} 2.375 2.5 V _{CCOC} 1.71 1.8 T _A -40	V _{CC} 3.135 3.3 3.45 V _{CC} 2.375 2.5 2.625 V _{CCOA/B} 3.135 3.3 3.45 V _{CCOA/B} 2.375 2.5 2.625 V _{CCOA/B} ¹ 1.71 1.8 1.89 V _{CCOC} 3.135 3.3 3.45 V _{CCOC} 2.375 2.5 2.625 V _{CCOC} 1.71 1.8 1.89 T _A -40 85

Note: Only for HCSL

Table 3 Electrical Characteristics

Unless otherwise specified: $Vcc = 3.3 \text{ V} \pm 5\%$, $2.5 \text{ V} \pm 5\%$, $Vcco = 3.3 \text{ V} \pm 5\%$, $Vcco = 3.3 \text{ V} \pm 5\%$, $Vcco = 3.3 \text{ V} \pm 5\%$, Vcco = 3.3 V, Vcco = 3.3 V,

Parameters	Conditions	Symbol	Min	Тур	Max	Units
	C	urrent Consun	ption			
Core supply current when input buffer is selected	CLKIN0/1 selected, $V_{CC} = 3.3 \text{ V/2.5 V} \pm 5\%,$ $V_{CC} = V_{CCO}$	I _{CC_CORE}		16.5	19.8	mA
Core supply current when Crystal is selected	XO selected, $V_{CC} = 3.3 \text{ V/2.5 V} \pm 5\%$, $V_{CC} = V_{CCO}$	I _{CORE_} xo ⁽⁴⁾			14	mA
Increment in core supply when all ODR banks are enabled		Icc_odr_en			2	mA
Frequency dependent current both bank on core supply. This current scales with frequency	For F _{in} = 2100 MHz	I _{CC_DYN} ⁽¹⁾⁽⁴⁾		25	33	mA
Additive output supply current per LVPECL bank enabled		I _{CCO_PECL}		165	204	mA



Parameters	Conditions	Symbol	Min	Тур	Max	Units
Additive output supply						
current per LVDS bank		I _{CCO_LVDS}		40	49	mA
enabled						
Additive output supply						
current per HCSL bank		I _{CCO_HCSL}		110	138	mA
enabled						
Additive output supply	F _{IN} = 200 MHz,	I _{CCO_CMOS}		6	7.2	mA
current, LVCMOS Output	$C_{LOAD} = 5 \text{ pF}, V_{CCO} = 3.3 \text{ V}$	000_000				
Enabled	$F_{IN} = 200 \text{ MHz},$			4.5	5.5	mA
	$C_{LOAD} = 5 \text{ pF}, V_{CCO} = 2.5 \text{ V}$					
		r Supply Rejec	tion Ratio	ı	T	
Ripple induced phase spur	Fin = 156.25 MHz,	5055				
level, supply ripple of	Foffset = 100 KHz	PSRR _{PECL}		-67		dBc
100mV pp	V _{CCOA/B} = 2.5 V					
Ripple induced phase spur	Fin = 156.25 MHz,					
level, supply ripple of	Foffset = 100 KHz	PSRR _{LVDS}		-70		dBc
100mV pp	V _{CCOA/B} =2.5 V					
Ripple induced phase spur	Fin = 156.25 MHz,					
level, supply ripple of	Foffset = 100 KHz	PSRR _{HCSL}		-67.7		dBc
100mV pp	V _{CCOA/B} = 2.5 V					
Input High Current	$V_{CC} = 3.3V$, $V_{IH} = V_{CC}$	I _{IH}		30	50	μA
	Input C	Control Pin Cha	aracteristic			
Input Low Current		I _{IL}	-20	0.1		μΑ
Input high voltage – Logic		V _{IH}	0.7*V _{cc}		V _{cc}	V
inputs		V IH	U.I VCC		V CC	V
Input low voltage – Logic		VII	GND		0.3*V _{CC}	V
inputs		V IL	GIND		U.S VCC	v
Internal Pull-down		R _{pulldown}		200		ΚΩ
resistance		• \pulldown		200		1 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \

Notes:

- 1. Total current from core supply at frequency Fin = I_{CORE, STATIC} + N*(0.5*Fin/2100M)* I_{CORE, DYN}. Detailed methodology of calculating the power dissipated in each ODR mode is given in the section "Current consumption and Power Dissipation Calculations." N is the number of output banks enabled.
- 2. Refer to Application Information section for more information on current consumption and power dissipation calculations.
- 3. Power supply ripple rejection, or PSRR, is defined as the single-sideband phase spur level (in dBc) modulated onto the clock output when a single-tone sinusoidal signal (ripple) is injected onto the Vcco supply. Assuming no amplitude modulation effects and small index modulation, the peak-to-peak deterministic jitter (DJ) can be calculated using the measured single-sideband phase spur level (PSRR) as follows: DJ (ps pk-pk) = [(2 * 10(PSRR / 20)) / (π * f_{CLK})] * 1E¹²
- 4. Specification is ensured by characterization and is not tested in production.

Table 4 Input Clock Characteristics

Unless otherwise specified: $Vcc = 3.3 \text{ V} \pm 5\%$, $2.5 \text{ V} \pm 5\%$, $Vcco = 3.3 \text{ V} \pm 5\%$, $2.5 \text$

Parameters	Conditions	Symbol	Min	Тур	Max	Units			
	Characteristics of Universal Input Clock Pins								
Input frequency range ⁽⁴⁾		F _{CLKin} (1)	DC		2100	MHz			
Differential input high voltage		V_{IHD}			V _{CC}	V			
Differential input low voltage	CLKin driven differentially	V _{ILD}	GND			V			
Peak differential input voltage swing ⁽²⁾		V_{ID}	0.15		1.3	V			
Differential input common	Input differential swing of 150 mV	V_{CMD}	0.25		V _{cc} -1.2	٧			
mode voltage	Input differential swing of 350 mV	▼ CMD	0.25		V _{cc} -1.1	V			

SiT92211 10 Output, Differential, Ultra Low Jitter Buffer



Parameters	Conditions	Symbol	Min	Тур	Max	Units
	Input differential swing of 800 mV		0.25		V _{CC} -0.9	V
Single ended input high	Inverting differential input held at V _{CC} /2, V _{CC} = 3.3 V	V _{IH}	2		V _{cc}	V
voltage	Inverting differential input held at V _{CC} /2, V _{CC} = 2.5 V	VIH	1.6		V _{cc}	
Single ended input low	Inverting differential input held at V _{CC} /2, V _{CC} = 3.3 V	V _{IL}	GND		1.3	V
voltage	Inverting differential input held at V _{CC} /2, V _{CC} = 2.5 V	V IL	GND		0.9	
Single ended input voltage swing (3)		V_{I_SE}	0.3		2	VPP
Single ended input common mode voltage		V _{CM}	0.25		V _{CC} -1.2	V
	Fin = 100 MHz, Foffset > 50 KHz			-84		dBc
Mux Isolation between the	Fin = 200 MHz, Foffset > 50 KHz	- ISO _{MUX} ⁽¹⁾ -		-82		dBc
two input clock paths	Fin = 500 MHz, Foffset > 50 KHz			-71		dBc
	Fin = 1000 MHz, Foffset > 50 KHz			-65		dBc
	Cr	ystal Characte	ristics			
Equivalent series resistance		ESR		35	60	Ω
Load capacitance		CL	6	8	10	pF
Shunt Capacitance		Со		2	3	pF
Power dissipated in the crystal		Drive level		100	200	uW
Mode of oscillation				Fundamental		
Crystal frequency range		Fosc ⁽¹⁾	8		50	MHz
External clock frequency	XO over drive or Bypass	F _{CLK}			250	MHz
range Maximum swing level on OSCin/OSCout pins	mode XO over drive or Bypass mode	Vmax			1.8	Vpp_se
Vih_se	Bypass DC coupled mode.	Vih	0.98			V
Vil_se	SEL[1] = 1 & SEL[0]=1	Vil			0.36	V
Crystal Phase jitter ⁽⁵⁾	RMS, integration BW 12 KHz to 5 MHz, F _{crystal} = 25 MHz. Crystal input select Measured at V _{CC} = V _{CCO} = 2.5 V	t _{jit} (1)		155		fs

Notes:

- 1. Specification is ensured by characterization and is not tested in production.
- 2. Refer to Parameter Measurement Information section for definition of VID and VOD voltages.
- 3. For clock input frequency ≥ 100 MHz, CLKinX can be driven with single-ended (LVCMOS) input swing up to 3.3 Vpp. For clock input frequency < 100 MHz, the single-ended input swing should be limited to 2 Vpp max to prevent input saturation (refer to Driving the Clock Inputs for interfacing 2.5 V/3.3 V LVCMOS clock input < 100 MHz to CLKinX).
- 4. If the input clock is initially absent when the chip is just powered up, it will take atleast 2 falling edge of clock cycles for the output to appear. Therefore, the buffer level translates DC only after it sees two consecutive falling edge of input clock
- 5. Crystal Phase Jitter is measure on following part number, 7M-25.000MAKV-T



Table 5 Output Clock Characteristics - LVPECL

Unless otherwise specified: V_{CC} = 3.3 V ± 5%, 2.5 V ± 5%, V_{CCO} = 3.3 V ± 5%, 2.5 V ± 5%, -40 °C ≤ T_A ≤ 85 °C, CLKin0/1 driven differentially, input slew rate ≥3 V/ns. Typical values represent most likely parametric norms at Vcc = 3.3 V, V_{CCO} = 3.3 V, T_A = 25 °C. Termination is 50 Ω to V_{CCO} -2V

Parameters	Condition	Symbol	Min	Тур	Max	Unit
Maximum output frequency, full VOD swing ≥ 600 mV ⁽¹⁾	50 Ω termination biased with V _{CCO} -2V	F _{CLKOUT_F} ⁽¹⁾	1000	1200	-	MHz
Maximum output frequency, full VOD swing ≥ 400 mV ⁽¹⁾			1500	2100		MHz
Additive RMS jitter ⁽¹⁾	Integration bandwidth from 10 KHz to 20 MHz, $F_{\text{IN}} = 156.25 \text{ MHz}, \\ \text{SR} > 3 \text{ V/ns}$ $50 \ \Omega \text{ termination biased}$ with V_{CCO} -2V	Jitter _{ADD} ⁽¹⁾		55		fs(rms)
Noise floor for Foffset > 10 MHz	50Ω termination biased with V _{CCO} -2V, F _{IN} = 156.25 MHz, SR > 3 V/ns	Noise _{FLOOR} ⁽¹⁾		-159		dBc
Output Duty Cycle	50Ω termination biased with V _{CCO} -2V	ODC	45		55	%
Output high voltage	50Ω termination biased with V _{CCO} -2V	V _{OH}	V _{CCO} - 1.165		V _{CCO} - 0.75	V
Differential output voltage	50Ω termination biased with V _{CCO} -2V	V _{OD}	475	678	960	mV
Output low voltage	50 Ω termination biased with V _{CCO} -2V	V _{OL}	V _{CCO} - 2.0		V _{CCO} – 1.45	V
Output rise time, 20% to 80%	50 Ω termination biased with V _{CCO} -2V	t _R		210	350	ps
Output fall time 20% to 80%	50Ω termination biased with V _{CCO} -2V	t _F		210	350	ps
Input to output delay	50Ω termination biased with V _{CCO} -2V	t _{pd}		876	1100	ps

Notes:

Table 6 Output Clock Characteristics - LVDS

Unless otherwise specified: V_{CC} = 3.3 V ± 5%, 2.5 V ± 5%, V_{CCO} = 3.3 V ± 5%, 2.5 V ± 5%, -40 °C ≤ T_A ≤ 85 °C, CLKin0/1 driven differentially, input slew rate ≥ 3 V/ns. Typical values represent most likely parametric norms at Vcc = 3.3 V, V_{CCO} = 3.3 V, V_{CCO} = 3.3 V, V_{CCO} = 3.5 °C.

Parameters	Conditions	Symbol	Min	Тур	Max	Units
Maximum output frequency, full VOD swing ≥ 250 mV	R_L = 100 Ω , differential	F _{CLKOUT_FS} ⁽¹⁾	1000	1600	-	MHz
Maximum output frequency, full VOD swing ≥ 200 mV	R_L = 100 Ω , differential		1500	2100		MHz
Additive RMS jitter	Integration bandwidth from 10 KHz to 20 MHz, Fin = 156.25 MHz, SR > 3 V/ns $R_L = 100 \ \Omega$, differential	Jitter _{ADD}		60		fs(rms)
Noise floor for Foffset > 10 MHz	Fin = 156.25 MHz, SR > 3 V/ns R_L = 100 Ω , differential	Noise _{FLOOR}		-159		dBc

^{1.} Specification is guaranteed by characterization and is not tested in production

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Parameters	Conditions	Symbol	Min	Тур	Max	Units
Output Duty Cycle	R_L = 100 Ω, differential	ODC	45		55	%
Change in VPP between complementary output states	R _L = 100 Ω, differential	ΔVPP			50	mV
Output differential peak voltage	R_L = 100 Ω, differential	V _{OD}	247		454	mV
Output Common-Mode Voltage	R_L = 100 Ω, differential	V _{OCM}	1.125	1.2	1.375	V
Output rise time, 20% to 80%	R_L = 100 Ω , differential, C_L < 5 pF	t _R		210	350	ps
Output fall time 20% to 80%	Uniform transmission line up to 10 inches with characterisitic impedance of 50 Ω	t _F		210	350	ps
Input to output delay		t _{pd}		840	1100	ps
Skew between outputs	V _{CCO} = 3.3 V, 2.5 V	T_sk		30		ps

Notes:

Table 7 Output Clock Characteristics - HCSL

Parameters	Conditions	Symbol	Min	Тур	Max	Units
Maximum output frequency	R_L = 50 Ω to GND	F _{CLKOUT_F} 1	DC		700	MHz
Additive RMS jitter	Integration bandwidth from	Jitter _{ADD} ⁽¹⁾		55		fs(rms)
Noise floor for Foffset > 10 MHz	10 KHz to 20 MHz, Fin = 156.25 MHz, SR > 3 V/ns R_L = 50 Ω to GND	Noise _{FLOOR} ⁽¹⁾		-159		dBc
Output Duty Cycle		ODC	45		55	%
Output Low Voltage Min		V _{MIN}	-300			mV
Differential Output High Voltage	$R_L = 50 \Omega$ to GND	V _{OH}	600	840	1150	mV
Differential Output Low Voltage		V _{OL}	-150	28	150	mV
Absolute Crossing point voltage	$R_L = 50 \Omega \text{ to GND},$	V _{CROSS}	250		550	mV
Variation of V _{CROSS} over all rising clock edges	C _L < 5 pF	V _{CROSS} DELTA			140	mV
Output rise time, 20% to 80%	F_{IN} = 156.25 MHz, Uniform transmission line up to 10	t _R		210	500	ps
Output fall time 20% to 80%	inches with characterisitic impedance of 50 Ω R _L = 50 Ω to GND, C _L < 5 pF	t _F		210	500	ps
Input to output delay		t _{pd}		825	1100	ps

Notes:

^{1.} Specification is ensured by characterization and is not tested in production.

^{1.} Specification is ensured by characterization and is not tested in production.



Table 8 Filtered Phase Jitter Parameters - PCle Common Clocked (CC) Architecture

Parameters	Conditions	Symbol	Min	Тур	Max	Units
	PCIe Gen 1 ^[1,2,3,4]	tj _{phPCleG1-CC}		2	5	ps (p-p)
	PCIe Gen 2 ^[1,2,3,4]	tj _{phPCleG2-CC}		0.08	0.15	ps(rms)
Additive Phase Jitter	PCIe Gen 3 ^[1,2,4,6]	tj _{phPCleG3-CC}		0.03	0.07	ps(rms)
	PCIe Gen4 ^[1,2,4,6]	tj _{phPCleG4-CC}		0.03	0.07	ps(rms)
	PCIe Gen5 ^[1,2,4,6]	tj _{phPCleG5-CC}		0.01	0.02	ps(rms)

Notes:

- 1. Applies to all the differential outputs, gauranteed by design and characterization.
- 2. Applies to all the Outputs when driven by a low phase noise source SMA100B.
- 3. Additive RMS Jitter Measurements were made using DSA90804A for minimum waveform length of ≥ 100k cycles with a minimum sampling rate of ≥ 40GSa/s with the waveform covering 90% of the DSO screen. All the post processing the DSO is disabled to decrease the additional jitter impact from oscilloscope. Broadband oscilloscope noise is also minimized in the measurement.
- 4. Additive jitter for RMS values is calculated by solving the equation for b [b=sqrt(c^2-a^2) where 'a' the rms input jitter and "c" is the rms total jitter.
- 5. Input to SiT92211 is fed using low phase noise source SMA100B, SiT92211 is configured as 100MHz HCSL Output Driver [Vccox = 3.3V] and fed to the channels of DSA90804A using the exact measurement set up [Refer Note 6]
- 6. SiT92211 PCI Express Additive RMS Jitter Measurement Set up configuration

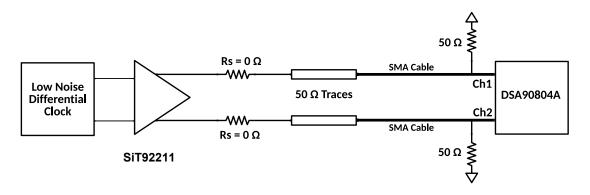


Table 9 Output Clock Characteristics – LVCMOS

Unless otherwise specified: $V_{CC} = 3.3 \text{ V} \pm 5\%$, $V_{CCO} = 3.3 \text{ V} \pm 5\%$, $2.5 \text{ V} \pm 5\%$, $-40 ^{\circ}\text{C} \leq T_A \leq 85 ^{\circ}\text{C}$, CLKin0/1 driven differentially, input slew rate $\geq 3 \text{ V/ns}$. Typical values represent most likely parametric norms at $V_{CC} = 3.3 \text{ V}$, $V_{CCO} = 3.3 \text{ V}$, $T_A = 25 ^{\circ}\text{C}$.

Parameters	Conditions	Symbol	Min	Тур	Max	Units
Output Frequency		f _{CLKOUT}	0		250	MHz
Additive RMS jitter	$V_{CCOC} = 3.3 \text{ V} \pm 5\%$	Jitter _{ADD} ⁽¹⁾		55		fs rms
Additive Kivio Jittei	$V_{CCOC} = 2.5 \text{ V} \pm 5\%$			63		fs rms
Noise floor for	$V_{CCOC} = 3.3 \text{ V} \pm 5\%$	Noise _{FLOOR} (1)		-159		dBc
Foffset > 10 MHz V _{CCOC}	V _{CCOC} = 2.5 V ± 5%			-157		dBc
	For Fin ≤ 200 MHz	ODC	45		55	%
Output Duty Cycle	For 200 MHz < Fin < 250 MHz		40		60	%
Output high voltage	V _{CCOC} = 3.3 V ± 5%, 1 mA pull down current	V _{OH}	V _{CCOC} -0.1 V			V
Output night voltage	V _{CCOC} = 2.5 V ± 5%, 1 mA pull down current		V _{CCOC} -0.1 V			V



Parameters	Conditions	Symbol	Min	Тур	Max	Units
Output low voltage	V _{CCOC} = 3.3 V ± 5%, 1 mA pull up current	V_{OL}			0.1	V
Output low voltage	V _{ccoc} = 2.5 V ± 5%, 1 mA pull up current				0.1	V
Output rise time, 20% to 80%	$C_{LOAD} = 5 \text{ pF}, R_{LOAD} = 50 \Omega$	t _R		250	450	ps
Output fall time 20% to 80%	AC coupled	t _F		250	450	ps
Output enable time		t _{EN} ⁽¹⁾			4	cycles
Output disable time		t _{DIS} ⁽¹⁾			4	cycles
Input to clock edge to	V _{CCO} = 3.3 V, PCB trace of 5 inch, 5 pF capacitor	t _d ⁽¹⁾		1.4	2.5	ns
output clock edge delay	V _{CCO} = 2.5 V, PCB trace of 5 inch, 5 pF capacitor			1.5	2.7	ns

Notes:

^{1.} Specification is ensured by characterization and is not tested in production.

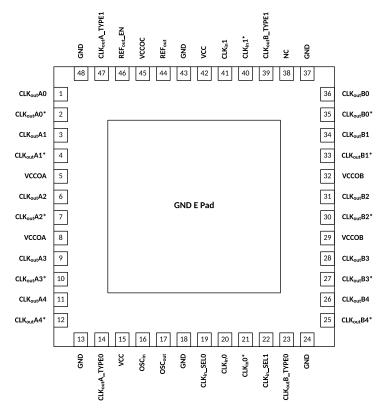


Figure 2 SiT92211 Pin configuration top view

Table 10 Pin Description

Pin Name	Pin Number	Functionality SiT92211		
	Pin group: Bank A clock output pads			
CLKoutA0	1	Differential clock output P of A0. Output type set by CLKoutA_TYPE pins.		
CLKoutA0*	2	Differential clock output N of A0. Output type set by CLKoutA_TYPE pins.		
CLKoutA1	3	Differential clock output P of A1. Output type set by CLKoutA_TYPE pins.		
CLKoutA1*	4	Differential clock output N of A1. Output type set by CLKoutA_TYPE pins.		
CLKoutA2	6	Differential clock output P of A2. Output type set by CLKoutA_TYPE pins.		





CLKoutA2* 7	Pin Name	Pin Number	Functionality SiT92211	
CLKouth3** 10 Differential clock output P of A3. Output type set by CLKouth_TYPE pins. CLKouth4** 11 Differential clock output N of A3. Output type set by CLKouth_TYPE pins. CLKouth4** 12 Differential clock output N of A3. Output type set by CLKouth_TYPE pins. Pin group: Bank & clock output pads CLKouth5** 12 Differential clock output N of A4. Output type set by CLKouth_TYPE pins. Pin group: Bank & clock output pads CLKouth6** 36 Differential clock output N of B0. Output type set by CLKouth_TYPE pins. CLKouth6** 37 Differential clock output N of B0. Output type set by CLKouth_TYPE pins. CLKouth8** 31 Differential clock output N of B1. Output type set by CLKouth_TYPE pins. CLKouth8** 32 Differential clock output N of B1. Output type set by CLKouth_TYPE pins. CLKouth8** 33 Differential clock output N of B1. Output type set by CLKouth_TYPE pins. CLKouth8** 30 Differential clock output N of B2. Output type set by CLKouth_TYPE pins. CLKouth8** 27 Differential clock output N of B3. Output type set by CLKouth_TYPE pins. CLKouth8** 27 Differential clock output N of B3. Output type set by CLKouth_TYPE pins. CLKouth8** 27 Differential clock output N of B3. Output type set by CLKouth_TYPE pins. CLKouth8** 27 Differential clock output N of B3. Output type set by CLKouth_TYPE pins. CLKouth8** 25 Differential clock output N of B4. Output type set by CLKouth_TYPE pins. Pin group: Bank C clock output pad. Pin group: Bank C clock output pad. Pin group: Bank C clock output pad. CLKin0** 20 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKin0** 21 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKin1** 40 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKin1** 40 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKin1** 40 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKouth** 50 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKouth** 70 Unput for crystal. It can be over driven by an AG Jounh 1.50 OSCour				
CLKoutA3*		9		
CLKoutA4* 11 Differential clock output P of A4. Output type set by CLKoutA, TYPE pins. Pin group: Bank B clock output P of 64. Output type set by CLKoutA, TYPE pins. CLKoutB0 36 Differential clock output P of B0. Output type set by CLKoutB, TYPE pins. CLKoutB0* 35 Differential clock output P of B1. Output type set by CLKoutB, TYPE pins. CLKoutB1* 34 Differential clock output P of B1. Output type set by CLKoutB, TYPE pins. CLKoutB1* 33 Differential clock output P of B1. Output type set by CLKoutB, TYPE pins. CLKoutB2* 31 Differential clock output P of B2. Output type set by CLKoutB, TYPE pins. CLKoutB3* 28 Differential clock output P of B2. Output type set by CLKoutB, TYPE pins. CLKoutB3* 27 Differential clock output P of B3. Output type set by CLKoutB, TYPE pins. CLKoutB3* 27 Differential clock output P of B3. Output type set by CLKoutB, TYPE pins. CLKoutB3* 27 Differential clock output P of B4. Output type set by CLKoutB, TYPE pins. CLKoutB4* 25 Differential clock output P of B4. Output type set by CLKoutB, TYPE pins. CLKoutB4* 25 Differential clock output P of B4. Output type set by CLKoutB, TYPE pins. Pin group: Bank C clock output pad REFour 44 LVCMOS clock out synchronized with differential clocks Pin group: Clock inputs CLKini0 20 Universal clock input 0 (*ve polarity) (differential/single-ended) CLKini1* 40 Universal clock input 1 (*ve polarity) (differential/single-ended) CLKini1* 41 Universal clock input 1 (*ve polarity) (differential/single-ended) CLKini1* 40 Universal clock input 1 (*ve polarity) (differential/single-ended) CLKini1* 40 Universal clock input 1 (*ve polarity) (differential/single-ended) CLKini2* CLKoutB4* OSCour 16 Universal clock input 1 (*ve polarity) (differential/single-ended) Input for crystal. Leave oSCout floating if OSCin is driven by a single-ended clock in crystal over driven by an Scout by CLKoutB4. Vcca 15 Clad supported 6p* to 10pF, fine 8 MHz to 50 MHz to 50 MHz Clad supported 6p* to 10pF, fine 8 MHz to 50 MHz Clad supported for HOSC, driven		10		
CLKoutA4* 12 Differential clock output N of AA, Output type set by CLKoutA_TYPE pins. Pin group: Bank B clock output P of 80. Output type set by CLKoutB_TYPE pins. CLKoutB0 36 Differential clock output P of 80. Output type set by CLKoutB_TYPE pins. CLKoutB1 34 Differential clock output P of 80. Output type set by CLKoutB_TYPE pins. CLKoutB1 33 Differential clock output P of 81. Output type set by CLKoutB_TYPE pins. CLKoutB2 31 Differential clock output N of 81. Output type set by CLKoutB_TYPE pins. CLKoutB2 30 Differential clock output N of 82. Output type set by CLKoutB_TYPE pins. CLKoutB3 28 Differential clock output P of 83. Output type set by CLKoutB_TYPE pins. CLKoutB3 28 Differential clock output P of 83. Output type set by CLKoutB_TYPE pins. CLKoutB3 27 Differential clock output P of 84. Output bype set by CLKoutB_TYPE pins. CLKoutB4 26 Differential clock output P of 84. Output bype set by CLKoutB_TYPE pins. CLKoutB4 25 Differential clock output P of 84. Output bype set by CLKoutB_TYPE pins. CLKoutB4 26 Differential clock output P of 84. Output bype set by CLKoutB_TYPE pins. CLKoutB4 27 Differential clock output P of 84. Output bype set by CLKoutB_TYPE pins. Pin group: Bank C clock output pad CLKind 0		11		
CLKoutB0 36 Differential clock output pades CLKoutB1 36 Differential clock output P of B0. Output type set by CLKoutB_TYPE pins. CLKoutB1 34 Differential clock output P of B1. Output type set by CLKoutB_TYPE pins. CLKoutB1 34 Differential clock output P of B1. Output type set by CLKoutB_TYPE pins. CLKoutB1 33 Differential clock output P of B2. Output type set by CLKoutB_TYPE pins. CLKoutB2 31 Differential clock output P of B2. Output type set by CLKoutB_TYPE pins. CLKoutB2 31 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB3 28 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB3 27 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB3 27 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB4 26 Differential clock output P of B4. Output type set by CLKoutB_TYPE pins. CLKoutB4 27 Differential clock output P of B4. Output type set by CLKoutB_TYPE pins. CLKoutB4 26 Differential clock output P of B4. Output type set by CLKoutB_TYPE pins. CLKoutB4 27 Differential clock output P of B4. Output type set by CLKoutB_TYPE pins. CLKoutB4 27 Differential clock output P of B4. Output type set by CLKoutB_TYPE pins. Pin group: Bank C clock output pad LVCMOS clock out synchronized with differential clocks Pin group: Clock inputs CLKino 20 Universal clock input 0 (+ve polarity) (differential/single-ended) CLKino 20 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKino 21 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKino 22 Universal clock input 1 (+ve polarity) (differential/single-ended) Linput for crystal. It can be over driven by an AC coupled single ended clock in crystal Lock input 1 (+ve polarity) (differential/single-ended) Linput for crystal. It can be over driven by an AC coupled single ended clock in crystal Lock input 1 (+ve polarity) (differential/single-ended) Linput for crystal. It can be over driven by an AC coupled single ended clock in crystal Lock inpu				
CLKoutB0 CLKoutB0 CLKoutB1 35 Differential clock output P of B0. Output type set by CLKoutB_TYPE pins. CLKoutB1 34 Differential clock output P of B1. Output type set by CLKoutB_TYPE pins. CLKoutB1 35 Differential clock output P of B1. Output type set by CLKoutB_TYPE pins. CLKoutB1 36 CLKoutB2 37 Differential clock output P of B2. Output type set by CLKoutB_TYPE pins. CLKoutB2 38 Differential clock output P of B2. Output type set by CLKoutB_TYPE pins. CLKoutB2 39 Differential clock output P of B2. Output type set by CLKoutB_TYPE pins. CLKoutB3 28 Differential clock output N of B2. Output type set by CLKoutB_TYPE pins. CLKoutB3 27 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB3 27 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB4 26 Differential clock output P of B3. Output type set by CLKoutB_TYPE pins. CLKoutB4 25 Differential clock output P of B4. Output type set by CLKoutB_TYPE pins. Pin group: Bank C clock output pad CLKind CLKind 20 Universal clock input 0 (**ve polarity) (differential clocks Pin group: Clock inputs CLKind 21 Universal clock input 0 (**ve polarity) (differential/single-ended) CLKind CLKind 41 Universal clock input 1 (**ve polarity) (differential/single-ended) Input for crystal. It can be over driven by an AC coupled single ended clock in crystal. Voc. 16 OSC _{DI} 17 Output for crystal. It can be over driven by an AC coupled single ended clock in crystal. Voc. 15 Voc. 16 Differential clock output to P on the max voltage at the pin needs to be 1.5 V. If the driver is swinging to say 3.3 V rall, then a resistor divider is needed on PCB to restrict the swing at Occupation of the Clk driver. Voc. 17 Output for crystal. It can be over driven by an AC coupled single ended clock in crystal. In the external bypass mode, the max voltage at the pin needs to be 1.5 V. If the driver is swinging to say 3.3 V rall, then a resistor divider is needed on PCB to restrict the swing at Occinity	-			
CLKoutB0* 35	CLKoutB0	•		
CLKoulB1 34 Differential clock output P of B1. Output type set by CLKoulB_TYPE pins. CLKoulB2 31 Differential clock output N of B1. Output type set by CLKoulB_TYPE pins. CLKoulB2 31 Differential clock output P of B2. Output type set by CLKoulB_TYPE pins. CLKoulB2 30 Differential clock output P of B2. Output type set by CLKoulB_TYPE pins. CLKoulB3 28 Differential clock output P of B3. Output type set by CLKoulB_TYPE pins. CLKoulB3* 27 Differential clock output P of B3. Output type set by CLKoulB_TYPE pins. CLKoulB4* 26 Differential clock output P of B3. Output type set by CLKoulB_TYPE pins. CLKoulB4* 25 Differential clock output P of B4. Output type set by CLKoulB_TYPE pins. CLKoulB4* 25 Differential clock output P of B4. Output type set by CLKoulB_TYPE pins. Pin group: Bank C clock out put pad REFour 44 LVCMOS clock out synchronized with differential clocks Pin group: Clock input 0 (eve polarity) (differential/single-ended) CLKin0 20 Universal clock input 0 (eve polarity) (differential/single-ended) CLKin1 41 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 41 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 41 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKoutA_Type 1 17 Output for crystal. It can be vere driven by an AC coupled single-ended clock input 1 (+ve polarity) (differential/single-ended) CLKoutA_Type 1 47 Bank A Output buffers Vecos can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank A Output buffers Vecos can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank				
CLKoutB1* 33 Differential clock output N of B1. Output type set by CLKoutB_TYPE pins. CLKoutB2* 31 Differential clock output N of B2. Output type set by CLKoutB_TYPE pins. CLKoutB3* 28 Differential clock output N of B2. Output type set by CLKoutB_TYPE pins. CLKoutB3* 28 Differential clock output N of B2. Output type set by CLKoutB_TYPE pins. CLKoutB3* 27 Differential clock output N of B3. Output type set by CLKoutB_TYPE pins. CLKoutB4* 26 Differential clock output N of B3. Output type set by CLKoutB_TYPE pins. CLKoutB4* 25 Differential clock output N of B4. Output type set by CLKoutB_TYPE pins. CLKoutB4* 25 Differential clock output N of B4. Output type set by CLKoutB_TYPE pins. PIn group: Bank C clock output N of B4. Output type set by CLKoutB_TYPE pins. PIn group: Bank C clock output Pad REFour 44 LVCMOS clock out synchronized with differential clocks PIn group: Clock input 0 (+ve polarity) (differential clocks PIn group: Clock input 0 (+ve polarity) (differential/single-ended) CLKin0* 20 Universal clock input 0 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 0 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (+ve polarity) (differential/single-ended) Input for crystal. It can be over driven an AC ooutpet single ended clock in crystal over driven mode. OSC _N 16 In the external bypass mode, the max voltage at the pin needs to be 1.5 V. If the dirve is swinging to say 3.3 V rail, then a resistor divider is needed on PCB to restrict the swing at Oscin to 1.5V Cload supported 6pfs 1 olopy. Fine g8 MHz to 60 MHz Vcco 42 Line supply -3.3 V/2.5 V Line supply -3.3 V/2.5 V Line supply -3.3 V/2.5 V Line supply For Bank A Output buffers. Vcco. can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL criver. Power supply for Bank B Output buffers. Vcco. can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL criver. Power supply for Bank B Output buffers. Vcco. can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL criver. Power supply for				
CLKoulB2				
CLKoutB2* 30 Differential clock output N of B2. Output type set by CLKoutB_TYPE pins.				
CLKoutB3				
CLKoutB3* 27				
CLKoutB4				
CLKoutB4* 25 Differential clock output N of B4. Output type set by CLKoutB_TYPE pins. Pin group: Bank C clock output pad				
Pin group: Bank C clock output pad				
REFour 44	02.100.0			
Pin group: Clock inputs	REFOUR	•		
CLKin0	1121 001			
CLKin0* 21	Cl Kin0	20	· · · · · · · · · · · · · · · · · · ·	
CLKin1 41 Universal clock input 1 (+ve polarity) (differential/single-ended) CLKin1* 40 Universal clock input 1 (-ve polarity) (differential/single-ended) Input for crystal. It can be over driven by an AC coupled single ended clock in crystal over driven work. In the external bypass mode, the max vollage at the pin needs to be 1.5 V. If the dirver is swinging to say 3.3 V rail, then a resistor divider is needed on PCB to restrict the swing at Oscin to 1.5 V Cload supported 6pF to 10pF, freq 8 MHz to 50 MHz OSCour 17 Output for crystal. Leave OSCout floating if OSCin is driven by a single- ended clock. Pin group: Power pins Vcc 15 Line supply - 3.3 V/2.5 V Power supply for Bank A Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank A Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffers. Vccoa can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffers. Vccoa can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffers. Occoa can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffers. Occoa can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power sup			, , , , , , , , , , , , , , , , , , , ,	
CLKin1* 40 Universal clock input 1 (-ve polarity) (differential/single-ended) Input for crystal. It can be over driven by an AC coupled single ended clock in crystal over drive mode. In the external bypass mode, the max voltage at the pin needs to be 1.5 V. If the dirver is swinging to say 3.3 V rail, then a resistor divider is needed on PCB to restrict the swing at Clock in 0.5 V. Cload supported 6pF to 10pF, freq 8 MHz to 50 MHz OSCour 17 Output for crystal. Leave OSCout floating if OSCin is driven by a single- ended clock. Pin group: Power pins Vcc 15 Line supply - 3.3 V/2.5 V Vcc 42 Line supply - 3.3 V/2.5 V Vcc 42 Line supply - 3.3 V/2.5 V Vcc 5 Power supply for Bank A Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Vccoa 8 Power supply for Bank A Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Vccoa 9 Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Vccoa 9 Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Vccoa 9 Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Vccoa 19 Power supply for Bank B Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Vccoa 19 Power supply for Bank C Output buffers. Vccoa can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffers. Vccoa can operate from 3.3 V or 2.5 V or 1.8 V is pround pin ground pi				
Input for crystal. It can be over driven by an AC coupled single ended clock in crystal over driven mode. In the external bypass mode, the max voltage at the pin needs to be 1.5 V. If the dirver is swinging to say 3.3 V rail, then a resistor divider is needed on PCB to restrict the swing at Oscin to 1.5 V. Cload supported 6pF to 10pF, freq 8 MHz to 50 MHz OSCour 17 Output for crystal. Leave OSCout floating if OSCin is driven by a single- ended clock. Pin group: Power pins Vcc 15 Line supply - 3.3 V/2.5 V Vcc 42 Line supply - 3.3 V/2.5 V VccoA 5 Power supply for Bank A Output buffers. VccoA can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoA 8 Power supply for Bank A Output buffers. VccoA can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 32 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 29 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoC 45 Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoC 45 Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoC 45 Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoC 45 Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer by CccB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffe				
OSC _{IN} 16 18 18 19 19 19 10 10 10 10 10 10 10	CLIMITI	40		
In the external bypass mode, the max voltage at the pin needs to be 1.5 V. If the dirver is swinging to say 3.3 V rail, then a resistor divider is needed on PCB to restrict the swing at Oscin to 1.5V Cload supported 6pF to 10pF, freq 8 MHz to 50 MHz				
dirver is swinging to say 3.3 V rail, then a resistor divider is needed on PCB to restrict the swing at Oscin to 1.5V Cload supported 6pF to 10pF, freq 8 MHz to 50 MHz OSCout 17 Output for crystal. Leave OSCout floating if OSCin is driven by a single- ended clock. Pin group: Power pins Vcc 15 Line supply - 3.3 V/2.5 V Line supply - 3.3 V/2.5 V Line supply - 3.3 V/2.5 V VccoA 5 Power supply for Bank A Output buffers. VccoA can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoA 8 Power supply for Bank A Output buffers. VccoA can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 29 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 29 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 29 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer for MCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer for MCSL driver. Power supply for Bank B Output buffer for MCSL driver. Power supply for Bank B Output buffer for MCSL driver. Pin group: Control pins CLKoutA_Type0 14 Bank A output buffer type selection pins	000	40		
Cload supported 6pF to 10pF, freq 8 MHz to 50 MHz	USCIN	16		
OSC _{OUT} 17 Output for crystal. Leave OSCout floating if OSCin is driven by a single- ended clock. Pin group: Power pins Vcc 15 Line supply - 3.3 V/2.5 V VccoA 2 Line supply - 3.3 V/2.5 V VccoA 5 Power supply for Bank A Output buffers. VccoA can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank A Output buffers. VccoA can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 32 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoB 29 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. VccoC 45 Power supply for Bank B Output buffers. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank C Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. Power supply for Bank B Output buffer. VccoB can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver.				
Pin group: Power pins				
V _{CC} 15 Line supply - 3.3 V/2.5 V V _{CC} 42 Line supply - 3.3 V/2.5 V V _{CCOA} 5 Power supply for Bank A Output buffers. V _{CCOA} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOA} 8 Power supply for Bank A Output buffers. V _{CCOA} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOB} 32 Power supply for Bank B Output buffers. V _{CCOB} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOB} 29 Power supply for Bank B Output buffers. V _{CCOB} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOC} 45 Power supply for Bank C Output buffer. V _{CCOB} can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. V _{CCOC} 45 Power supply for Bank C Output buffer. V _{CCOB} can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. V _{CCOC} 45 Power supply for Bank C Output buffer. V _{CCOB} can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. GND-EPAD 0 Ground GND 13 ground pin GND 18 ground pin GND 24 ground pin GND 48 ground pin GND 48 ground pin GND 48 ground pin GND 48 ground pin	OSC _{OUT}	17	, , ,	
Voc 42 Line supply - 3.3 V/2.5 V V _{CCOA} 5 Power supply for Bank A Output buffers. V _{CCOA} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOA} 8 Power supply for Bank A Output buffers. V _{CCOA} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOB} 32 Power supply for Bank B Output buffers. V _{CCOB} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOB} 29 Power supply for Bank B Output buffers. V _{CCOB} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOC} 45 Power supply for Bank C Output buffer. V _{CCOB} can operate from 3.3 V or 2.5 V or 1.8 V is supported for HCSL driver. GND-EPAD 0 Ground GND 13 ground pin (Found pi				
Power supply for Bank A Output buffers. V _{CCOA} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOA}				
Source S	V _{CC}	42		
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V _{CCOB} 29 Power supply for Bank B Output buffers. V _{CCOB} can operate from 3.3 V or 2.5 V. 1.8 V is supported for HCSL driver. V _{CCOC} 45 Power supply for Bank C Output buffer. V _{CCOC} can operate from 3.3 V or 2.5 V or 1.8 V GND-EPAD 0 Ground GND 13 ground pin GND 18 ground pin GND 24 ground pin GND 37 ground pin GND 48 ground pin GND 43 ground pin GND 43 ground pin Pin group: Control pins CLKoutA_Type0 14 Bank A output buffer type selection pins CLKoutA_Type1 47 Bank A output buffer type selection pins	V _{CCOB}	32		
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GND 48 ground pin GND 43 ground pin Pin group: Control pins CLKoutA_Type0 14 Bank A output buffer type selection pins CLKoutA_Type1 47 Bank A output buffer type selection pins	GND	37	ground pin	
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CLKoutA_Type1 47 Bank A output buffer type selection pins	CLKoutA Type0	14		
	CLKoutB Type0	23	Bank B output buffer type selection pins	





Pin Name	Pin Number	Functionality SiT92211	
CLKoutB_Type1	39	Bank B output buffer type selection pins	
REF _{OUT} _EN	46	REF _{OUT} enable input. Enable signal is internally synchronized to selected clock input.	
CLKin_SEL0	19	Clock input selection pins	
CLKin_SEL1	22	Clock input selection pins	
NC	38	No Connect, It should never be pulled high. It can be pulled low or left floating. If pulled high, chip behaviour will not be determined and is probabilistic.	



Functional Description

The SiT92211 is a 10-output differential clock fan out buffer with low additive jitter that can operate up to 2.1 GHz. It features a 3:1 input multiplexer with an optional crystal oscillator input, two banks of 5 differential outputs with multimode buffers (LVPECL, LVDS, HCSL, or Hi-Z), one LVCMOS output, and 3 independent output buffer supplies. The input selection and output buffer modes are controlled via pin strapping. The device is offered in a 48-pin WQFN package.

V_{CC} and V_{CCO} Power Supplies

The SiT92211 has separate 3.3/2.5 core (Vcc) and 3 independent 3.3 V/2.5 V output power supplies (VccoA, VccoB). HCSL can support 1.8V power supplies (VccoA, VccoB). V_{CCOC} supply can operate on 3.3 V/2.5 V/1.8 V rail. Output supply operation at 2.5 V enables lower power consumption and output-level compatibility with 2.5 V receiver devices. The output levels for LVPECL (Voh, Vol) and LVCMOS (Voh) are referenced to its respective Vcco supply, while the output levels for LVDS and HCSL are relatively constant over the specified Vcco range.

Clock Inputs

The input clock can be selected from CLKin0/CLKin0*, CLKin1/CLKin1*, or OSCin. Clock input selection is controlled using the CLKin_SEL[1:0] inputs as shown in Table 11. When CLKin0 or CLKin1 are selected, the oscillator is power down. The user can float OSCin and OSCout pins, since these pins are internally pulled down. OSCin is pulled down with a 56 K Ω resistance.

Table 11 Input Clock Selection

CLKin_SEL [1]	CLKin_SEL [0]	Selected Clock
0	0	CLKin0, CLKin0*
0	1	CLKin1, CLKin1*
1	0	Crystal Or Crystal Bypass AC Coupled mode
1	1	Crystal bypass DC Coupled mode

Clock States (Input vs Output States)

Table 12 Input versus Output Stages

State of Selected Clock input	Output State
Inputs are floating	Logic low
Inputs are logic low	Logic low
Inputs are logic high	Logic high

Output Driver Type

The differential output buffer type for Bank A and Bank B outputs can be separately configured using the CLKoutA_TYPE[1:0] and CLKoutB_TYPE[1:0] inputs, respectively, as shown Table 13. For applications where all differential outputs are not needed, any unused output pin should be left floating with a minimum copper length to minimize capacitance and potential coupling and reduce power consumption. If an entire output bank will not be used, it is recommended to disable (Hi-Z) the bank to reduce power.

Table 13 OE Functionality

CLKOUTX_TYPE1	CLKOUTX_TYPE0	CLK Buffer Type
0	0	LVPECL
0	1	LVDS
1	0	HCSL
1	1	HIZ

Reference Output

The reference output (REF_{OUT}) provides a LVCMOS copy of the selected input clock. The LVCMOS output high level is referenced to the V_{CCOC} voltage. REF_{OUT} can be enabled or disabled using the enable input pin, REF_{OUT}_EN, as shown in Table 14. The reference output clock is internally synchronized to the selected clock. This avoids any glitches or runt pulses while enabling or disabling the reference clock. Pulling REF_{OUT}_EN to LOW, forces the outputs to the high-impedance state with in 4 falling edges of the input signal. The outputs remain in the high-impedance state as long as REF_{OUT}_EN is LOW. When REF_{OUT}_EN goes from HIGH to LOW, the output clock is disabled within 4 falling edges of the input clock signal. The output is disabled at the falling edge of the input clock. This allows to disable the output clock in a glitch free manner.

When REF_{OUT}_EN goes from low to high, the output clock is enabled within a time delay td, where td is given by the following equation.

$$t_{d.refout\ en} = 0.5n + 3 * Tin.$$

Where, Tin is the time period of the input clock.

When REF_{OUT}_EN is disabled, the use of a resistive loading can be used to set the output to a predetermined level. For example, if REF_{OUT}_EN is configured with a 1K Ω load to ground, then the output will be pulled to low when disabled.

Table 14 Reference Output Enable

Ref _{out_} EN	Output State
0	Disabled (HiZ)
1	Enabled



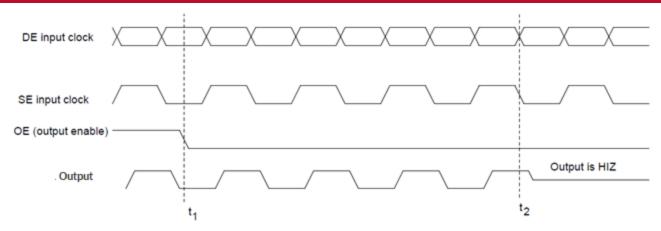


Figure 3 REF_{OUT}_EN: Output disable

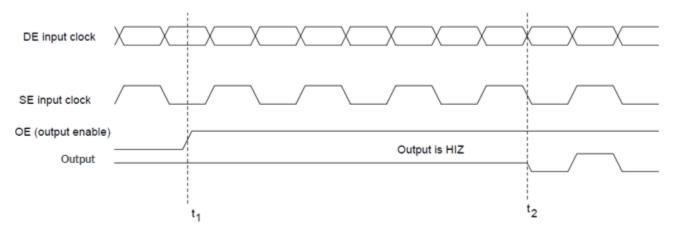


Figure 4 REFOUT_EN: Output enable



Application Information

Current consumption and Power Dissipation Calculations

The current consumption specified in the Electrical Characteristics can be used to calculate the total power dissipation and the IC power dissipation for any output driver configuration. The total current drawn from the V_{CC} is given by the equation below.

$$I_{CC} = I_{CORE,STATIC} + n * \left(\frac{f_{in}}{100}\right) * I_{CORE,DYN}$$

- *I_{CC}*, is the total core current drawn from V_{CC}.
- I_{CORE,STATIC}, is the current drawn by SiT92211, when clocks are not toggling and both the output driver banks are in HIZ state.
- I_{CORE,DYN}, is the switching current taken from V_{CC} when the selected input clock is toggling at a frequency of f_{in}.
- *n*, is the number of output banks that are active.

Current consumed by the output supplies in each mode are listed below.

- The current in output bank A/B in LVPECL mode is $I_{CCOA} = I_{CCOB} = I_{CC_LVPECL}$
- The current in output bank A/B in LVDS mode is $I_{CCOA} = I_{CCOB} = I_{CC_LVDS}$
- The current in output bank A/B in HCSL mode is $I_{CCOA} = I_{CCOB} = I_{CC\ HCSL}$
- The current in output bank C is $I_{CCOC} = I_{CC\ LVCMOS}$

The equation for the total power dissipation is

$$P_{TOTAL} = V_{CC} * I_{VCC} + V_{CCOA} * I_{CCOA} + V_{CCOB} * I_{CCOB} + V_{CCOC} * I_{CCOC}$$

If the output driver configuration is LVPECL or LVDS, then the power dissipated in any termination resistors and termination voltages need to be accounted to calculate the power dissipation in the device.

The power dissipated in the termination resistor in LVPECL mode is given below.

$$P_{RT_PECL} = \frac{\left(V_{OH_PECL} - V_{TT}\right)^2}{R_T} + \frac{\left(V_{OL_PECL} - V_{TT}\right)^2}{R_T}$$

The power dissipated in the termination voltage for LVPECL mode is given below

$$P_{VTT_PECL} = V_{TT} * \left(\frac{\left(V_{OH_PECL} - V_{TT} \right)}{R_T} + \frac{\left(V_{OL_PECL} - V_{TT} \right)}{R_T} \right)$$

The power dissipated in the ground referenced termination resistor for HCSL is given below

$$P_{RT_HCSL} = \frac{V_{OH_HCSL}^2}{R_T}$$

The power dissipated in the device is given below.

$$P_{DEVICE} = P_{TOTAL} - N_1 * (P_{RT_{PECL}} + P_{VTT_{PECL}}) - N_2 * P_{RT_HCSL}$$

Example: Worst case power dissipation

BANK A and BANK B output drivers are configured in LVPECL mode. The input frequency is 2100 MHz. $V_{\rm CC} = 3.465$, $V_{\rm CCOA} = V_{\rm CCOB} = V_{\rm CCOC} = 3.465$, REFout is enabled. Assume 5 pF load for REFout.

Table 15 Worst Case Power Dissipation

Parameter	Value	Unit
V _{cc}	3.465	V
V _{ccoa}	3.465	V
V _{CCOB}	3.465	V
V_{ccoc}	3.465	V
I_{cc}	52	mA
I _{CCOA}	198	mA
I _{ccob}	198	mA
Iccoc	10	mA
P _{TOTAL}	1588	mW
V _{OH_PECL}	2.5	V
V _{OL_PECL}	1.8	V
V_{TT}	1.465	V
P _{RT_PECL}	24	mW
P _{VTT_PECL}	40	mW
P _{DEVICE}	948	mW

Driving the Clock Inputs

SiT92211 has two universal clock inputs (CLKin0/CLKin0* and CLKin1/CLKin1*). SiT92211 can accept 3.3 V/2.5 V LVPECL, LVDS, CML, SSTL, and other differential and single-ended signals that meet input common mode, slew rate and swing requirements specified in the Electrical Characteristics. The SiT92211 supports a wide common mode voltage range and input signal swing To achieve the best possible phase noise and litter performance, it is mandatory for the input to have high slew rate of 3 V/ns (differential) or higher. Driving the input with a lower slew rate will degrade the noise floor and jitter. It is recommended to drive the input signal differentially for better slew rate and jitter. The user can also drive a single ended clock. If the user is driving the single ended clock signal on say CLKin0, then CLKin0* pin need to be connected to a 0.1 uF capacitor on the PCB.

Driving Clock Inputs with LVCMOS Driver (AC coupled)

Figure 5 shows how a differential input can be wired to accept LVCMOS single ended levels in AC coupled mode.



The bypass capacitor (C1) is used to help filter noise on the DC bias on the inverting pin of the clock input. This bypass should be located as close to the input pin as possible. Two resistors R_{T1} and R_{T2} set the common mode voltage at the output of the LVCMOS driver to $V_{CC}/2$. This prevents average DC leakage current from the LVCMOS driver and avoids unnecessary power dissipation.

For example, if the input clock is driven from a single-ended 2.5 V LVCMOS driver and the DC offset (or swing center) of this signal is 1.25 V, the R_{T1} and R_{T2} values should be adjusted to set the V1 at 1.25 V. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in the

following way. First, R_{T1} and R_{T2} in parallel should equal the transmission line impedance. For most 50 Ω applications, R_{T1} and R_{T2} can be 100 $\Omega.$

$$Z_o = R_o + R_s = 50 \Omega$$

$$\frac{R_{T1} * R_{T2}}{R_{T1} + R_{T2}} = 50 \ \Omega$$

$$\frac{Vcc * R_{T2}}{R_{T1} + R_{T2}} = \frac{Vcc}{2}$$

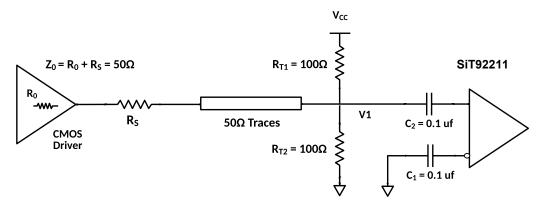


Figure 5 AC coupling LVCMOS clock to SiT92211

The inverting differential input can be connected to a 0.1 uF bypass capacitor. This pin is biased internally to a voltage close to $V_{\rm CC}/2$.

Another variant of the AC coupling of LVCMOS input clock is shown in Figure 6. We use single termination resistor of

 $50~\Omega$ to ground. A 0.1 uF (C3) ac coupling capacitor is connected in series with the LVCMOS clock source to prevent DC leakage current.

$$Z_o = R_o + R_s = 50 \, Ohm$$

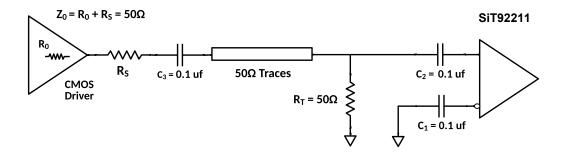


Figure 6 AC coupling of LVCMOS clock with single 50 Ω resistor termination to ground



Driving Clock Inputs with LVCMOS Driver (DC coupled)

Figure 7 shows how a differential input can be wired to accept LVCMOS single ended clock signals in DC coupled mode. The reference voltage V1 = $V_{\rm CC}/2$ is generated by the bias resistors $R_{\rm S1}$ and $R_{\rm S2}$. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of $R_{\rm S1}$ and $R_{\rm S2}$ might need to be adjusted to position the bias voltage V2 in the center of the input voltage swing.

$$Z_o = R_o + R_s = 50 \Omega$$

$$\frac{Vcc * R_{s2}}{R_{s1} + R_{s2}} = \frac{Vcc}{2}$$

$$\frac{R_{T1} * R_{T2}}{R_{T1} + R_{T2}} = 50 \ \Omega$$

$$\frac{Vcc * R_{T2}}{R_{T1} + R_{T2}} = \frac{Vcc}{2}$$

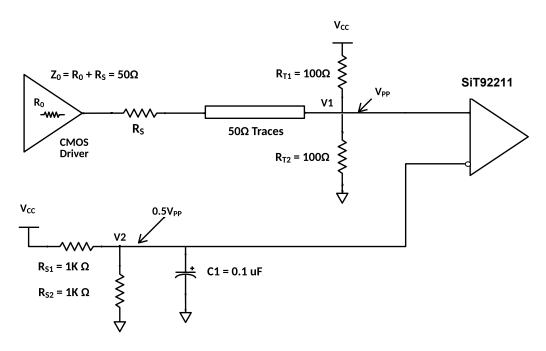


Figure 7 DC coupling of LVCMOS clock to SiT92211 - configuration 1

For example, if the input clock is driven from a single-ended 2.5 V LVCMOS driver and the DC offset (or swing center) of this signal is 1.25 V, the $R_{\rm S1}$ and $R_{\rm S2}$ values should be adjusted to set the V2 at 1.25 V. The values given below are for when both the single ended swing and $V_{\rm CC}$ are at the same voltage.

This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R_{T1} and R_{T2} in parallel should equal the transmission line impedance. For most 50 Ω applications, R_{T1} and R_{T2} can be 100 Ω . The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver.

Figure 8 shows a second input clock configuration where R_{T1} , R_{T2} are removed and replaced with a 50 Ω termination resistor R_T to ground. It is possible that LVCMOS driver (or clock source) may not be able to drive 50 Ω load in DC coupled mode. The user can use series RC termination to overcome this limitation. The design equations for the input clock configuration shown in Figure 8 is given below

$$Z_o = R_o + R_s = 50 \Omega$$

$$\frac{Vcc*R_{s2}}{R_{s1}+R_{s2}} = \frac{Vpp}{2}$$



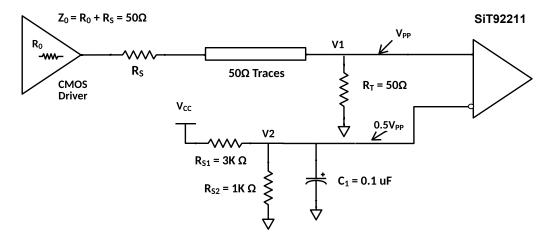


Figure 8 DC coupled LVCMOS input clock configuration – configuration 2

The LVCMOS single ended clock input with series RC termination near the buffer is shown in Figure 9. There is a single termination resistor RT which is connected to ground through a capacitor C_{AC} .

The value of series capacitor is given by a formula. $C_{AC} > \frac{3T_D}{C_{AC}}$

Where T_D is the transmission line delay

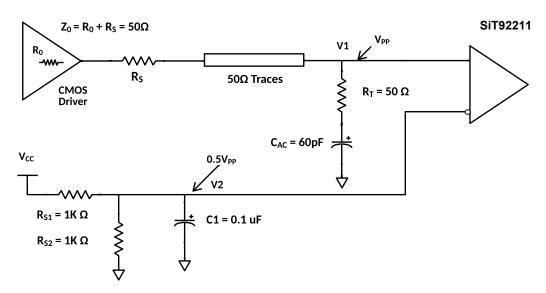


Figure 9 DC coupled LVCMOS input clock with series RC termination - configuration 3



For low frequencies we can direct couple the LVCMOS clock to SiT92211 input clock pin as shown in Figure 10.

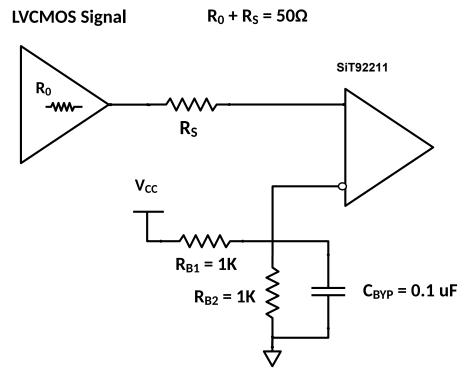


Figure 10: Direct coupling of LVCMOS clock to SiT92211

Driving OSC_IN with LVCMOS Driver (AC coupled)

The crystal input OSC_IN can be overdriven with single ended clock (LVCMOS driver or one side of a differential driver). The peak swing at OSC_IN should be limited to 1.8 V. The OSC_OUT pin, in this case can be floating. The SEL1, SEL0 should be 2'b10. The maximum voltage at OSC_IN should not exceed 1.8 V and minimum voltage should not go below -0.5 V. The slew rate at OSC_IN should be greater than 0.2 V/ns.

For 3.3 V LVCMOS inputs, the amplitude must be reduced from full swing to at least half the swing in order to prevent signal interference with the power rail and to reduce internal noise. Figure 11 shows an example of the interface diagram for a high speed 3.3 V LVCMOS driver. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First, R_{T1} and R_{T2} in parallel should

equal the transmission line impedance. For most 50 Ω applications, R_{T1} and R_{T2} can be 100 Ω .

$$Z_o = R_o + R_s = 50 \text{ Ohm}$$

$$\frac{R_{T1} * R_{T2}}{R_{T1} + R_{T2}} = 50 \text{ Ohm}$$

$$\frac{Vcc * R_{T2}}{R_{T1} + R_{T2}} = \frac{Vcc}{2}$$

For both the AC coupled configurations, the maximum peak to peak swing before the ac coupling capacitor is 1.8 V. The maximum DC bias voltage of OSC_IN is 0.675 V. Therefore the maximum swing at the OSC_IN pin is given by the equation given below.

$$V_{swing.pk.XTAL\ IN} = 0.675 + 0.5 * 1.8 = 1.575V$$



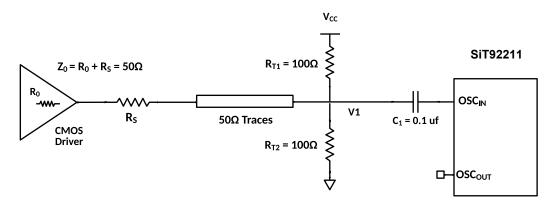


Figure 11 Single ended LVCMOS input - configuration 1, AC coupling to crystal input

Figure 12 shows a second input clock configuration where R_{T1} , R_{T2} are removed and replaced with a 50 Ω termination

resistor R_T to ground. A 0.1 uF is in series with the CMOS driver to prevent any DC leakage current.

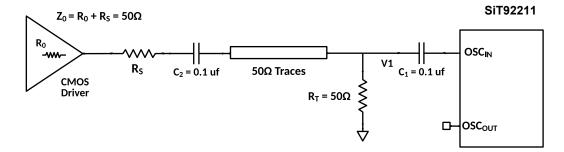


Figure 12 Single ended LVCMOS input - configuration 2, AC coupling to crystal input



Driving OSC_IN with LVCMOS Driver (DC coupled)

The crystal input OSC_IN can be overdriven with single ended clock as shown in Figure 13, in DC couple mode. The peak swing at OSC_IN should be limited to 1.8 V (voltage at the crystal input pin). The OSC_OUT pin, in this

case can be floating. The SEL1, SEL0 should be 2'b11. If the LVCMOS driver is on higher supply, say $3.3~\rm V$, use a resistor divider on the PCB to scale down the peak output voltage to $1.8~\rm V$

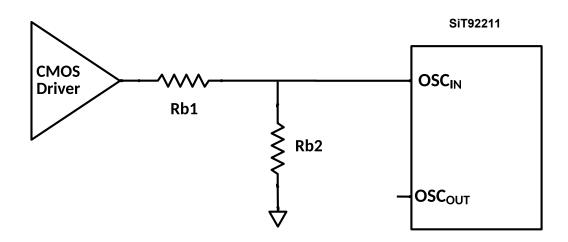


Figure 13 Single ended LVCMOS input, DC coupling to crystal input

LVDS (DC coupled)

Terminate with a differential 100 Ω as close to the receiver as possible. This is shown in Figure 14.

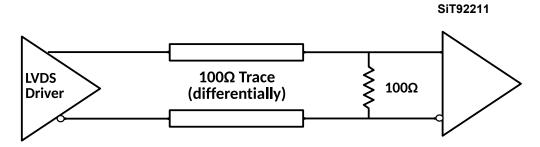


Figure 14 Termination scheme for DC coupled LVDS



HCSL (DC coupled)

Termination resistor is 50 Ω to ground, close to the output driver. A series resistance Rs is sometimes used to limit the

overshoot during fast transients. The terminationscheme is shown in Figure 15.

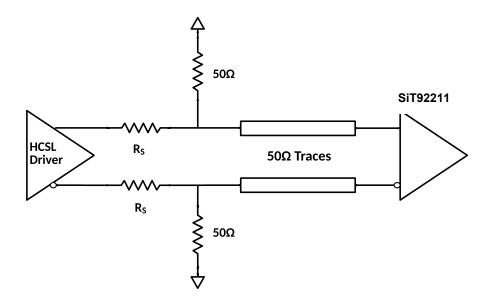


Figure 15 Termination scheme for DC coupled HCSL

LVPECL (DC coupled)

For DC couple operation, the 50 Ω termination resistors are placed close to the receiver. The termination resistors are biased with a voltage source VTT.

$$V_{TT} = V_{CCO} - 2V.$$

This termination scheme is shown in Figure 16. Alternatively, the user can also implement a Thevenin equivalent of VTT using a resistor divider. This scheme and the values of the resistors in the resistor divider are given in Figure 17

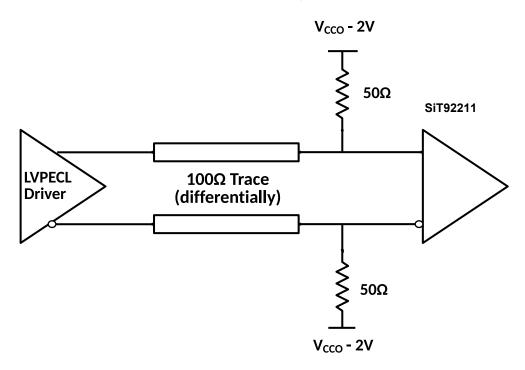


Figure 16 Termination scheme for DC coupled LVPECL



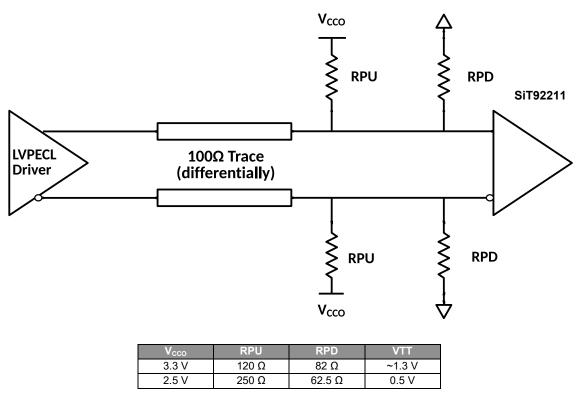


Figure 17 Termination scheme for DC coupled LVPECL, Thevenin equivalent

The design equations for the LVPECL Thevenin equivalent termination are given below.

$$\frac{R_{PD} * R_{PU}}{R_{PD} + R_{PU}} = 50\Omega$$

$$\frac{R_{PD}*Vcco}{R_{PD}+R_{PU}}=Vcco-2V$$

SSTL (DC coupled)

The SSTL input clock configuration is shown in Figure 18. The transmission line impedance is 60 Ω in the application example given. Therefore we use two 120 Ω resistors from V_{CCO} to ground for biasing the clock input pins. The effective termination impedance in this case is 60 Ω .



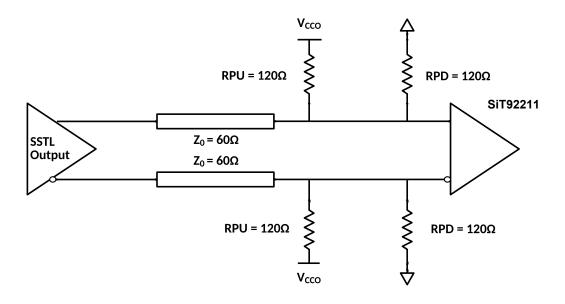


Figure 18 Example of input clock termination for SSTL clock.

LVDS (AC coupled)

The load termination resistor should be placed before the AC coupling capacitors. The load termination resistor and

the AC coupling capacitors should be placed close to the receiver. The termination scheme is shown in Figure 19.

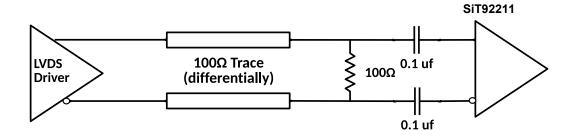


Figure 19 Termination scheme for AC coupled LVDS



LVPECL (AC coupled)

The LVPECL should have a DC path to ground. So, the user must place a resistance R_T , close to the output driver. The

LVPECL AC coupling and Thevenin equivalent VTT termination scheme is shown in Figure 20.

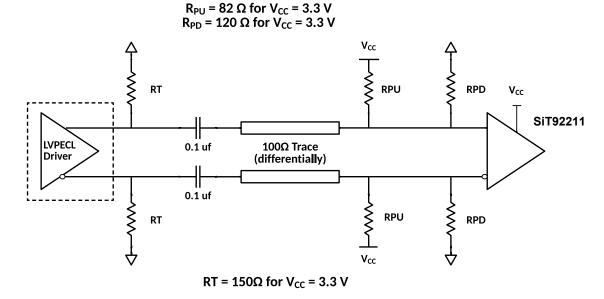


Figure 20 Termination scheme for AC coupled LVPECL, Thevenin Equivalent

The pull up resistance RPU and pull down resistance RPD sets the input common mode voltage for SiT92211. The value of the input common mode voltage can be estimated by the equation given below

$$V_{ICM} = \frac{Vcc * R_{PD}}{R_{PU+R_{PD}}} = \frac{3.3 * 120}{120 + 82} = 1.961 V$$

The differential input common mode specification of SiT92211 (from data sheet) is $V_{\rm CC}$ -1.1 = 2.2 V, therefore the input common mode set by LVPECL AC coupled termination meets the SiT92211 input common mode

specification. The LVPECL driver chip has resistance RT providing DC path for the output driver current in the LVPECL driver.

The effective load impedance at the input side of SiT92211 (receiver side) is formed by parallel combination of RPU, RPD.

The effective termination resistor value is given by the equation below

$$R_{termination} = \frac{R_{PU}*R_{PD}}{R_{PU} + R_{PD}} = \frac{120*82}{120 + 82} = 48.7 \,\Omega$$

Termination of Output Driver of SiT92211 for Various Load Configurations SiT92211 REF_{OUT} Termination for AC Coupled mode

AC coupling of SiT92211 LVCMOS output driver is shown in Figure 21. We use single termination resistor of 50 Ω to ground. A 0.1 uF AC coupling capacitor is connected in series with the LVCMOS clock source to prevent DC leakage current. The receiver side is terminated with a single 50 Ω resistance to ground. The clock signal is then

AC coupled to the receiver, in this example. C1 is a bypass capacitor that is used to suppress noise on the inverting differential input of the receiver.

$$Z_o = R_o + R_s = 50 \Omega$$



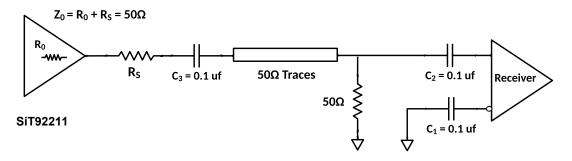


Figure 21 AC coupling of LVCMOS clock with single 50 Ω resistor termination to ground

SiT92211 REF_{OUT} Termination for DC Coupled mode

Figure 22 shows how SiT92211 LVCMOS output drive can be terminated to send clock signals in DC coupled mode. The reference voltage V1= $V_{\rm CC}/2$ is generated by the bias resistors $R_{\rm S1}$ and $R_{\rm S2}$. The bypass capacitor (C₁) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of $R_{\rm S1}$ and $R_{\rm S2}$ might need to be adjusted to position the bias voltage V2 in the center of the input voltage swing.

$$Z_o = R_o + R_s = 50 \ \Omega$$

$$\begin{split} \frac{\textit{Vcc}*\textit{R}_{s2}}{\textit{R}_{s1} + \textit{R}_{s2}} &= \frac{\textit{Vcc}}{2}, \\ \textit{Typical value of } \textit{R}_{s1} &= \textit{R}_{s2} = 1 \text{ K}\Omega \\ \frac{\textit{R}_{T1}*\textit{R}_{T2}}{\textit{R}_{T1} + \textit{R}_{T2}} &= 50 \text{ }\Omega, \\ \textit{Typical value of } \textit{R}_{T1} &= \textit{R}_{T2} = 100 \text{ }\Omega \\ \frac{\textit{Vcc}*\textit{R}_{T2}}{\textit{R}_{T1} + \textit{R}_{T2}} &= \frac{\textit{Vcc}}{2} \end{split}$$

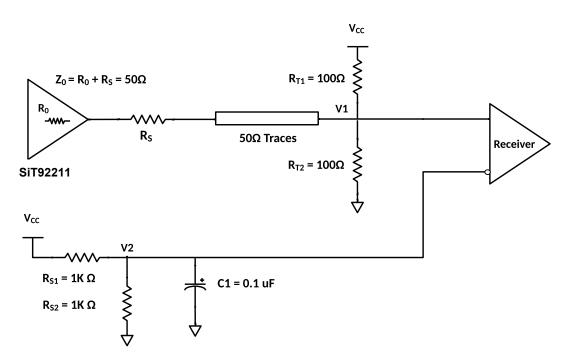


Figure 22 DC coupling of LVCMOS output clock termination - configuration 1



For example, if the SiT92211 supply is 2.5 V then the DC offset (or swing center) of this signal is 1.25 V, the $R_{\rm S1}$ and $R_{\rm S2}$ values should be adjusted to set the V2 at 1.25 V. The values given below are for when both the single ended swing and $V_{\rm CC}$ are at the same voltage.

This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R_{T1} and R_{T2} in parallel should equal the transmission line impedance. For most 50 Ω applications, R_{T1} and R_{T2} can be 100 Ω . The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver.

Figure 23 shows a second input clock configuration where R_{T1} , R_{T2} are removed and replaced with a 50 Ω termination resistor R_T to ground. There will be DC leakage current from SiT92211, for the output termination shown in Figure 23. The user can use series RC termination to overcome this limitation. The design equations for the input clock configuration shown in Figure 23 is given below

$$Z_o = R_o + R_s = 50 \,\Omega$$

$$\frac{Vcc * R_{s2}}{R_{s1} + R_{s2}} = \frac{Vpp}{2} = \frac{Vcc}{4},$$

Typical value of $R_{s1}=3~K\Omega$, $R_{s2}=1~K\Omega$

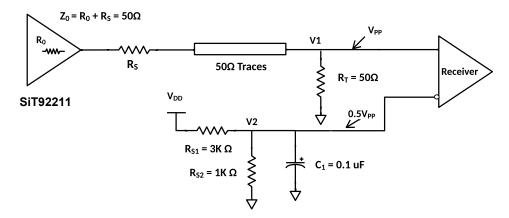


Figure 23 DC coupled LVCMOS output clock configuration - configuration 2

The SiT92211 LVCMOS output driver termination with series RC termination near the buffer is shown in Figure 24. There is a single termination resistor RT which is connected to ground through a capacitor CAC. The value of series capacitor is given by a formula.

$$C_{AC} \ge \frac{3T_D}{50\Omega}, T_D$$

is the transmission line delay

Typical value for C_{AC} is 60 pF, assuming delay of $T_D = 200$ ps/inch and 5 inch input clock route length



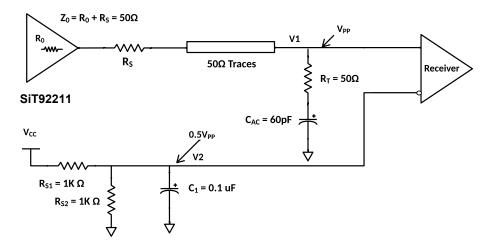


Figure 24 DC coupled LVCMOS output clock with series RC termination – configuration 3

The typical value of R_{S1} and R_{S2} in this case is 1K Ω and that of C_{AC} is 60 pF.

CMOS (Capacitive load)

The capacitive load can be driven as shown in Figure 25 For SiT92211 LVCMOS driver the Ro is very close to 50 Ω by design. Therefore Rs = 0 Ω is recommended.

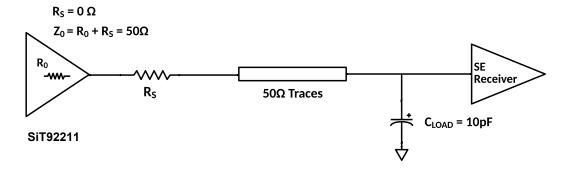


Figure 25 Typical application load



Termination of Output Drivers (DC coupled) LVDS DC Coupled Output Termination

Terminate with a differential 100 Ω as close to the receiver as possible. This is shown in Figure 26.

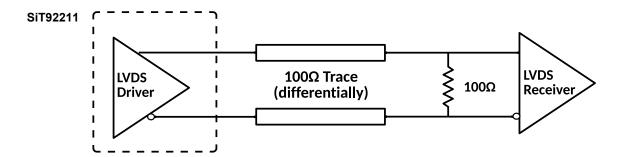


Figure 26 Termination scheme for DC coupled LVDS

HCSL DC Coupled Output Termination

Termination resistor is 50 Ω to ground, clos to the output driver. A series resistance Rs is sometimes used to limit the

overshoot during fast transients. The termination scheme is shown in Figure 27.

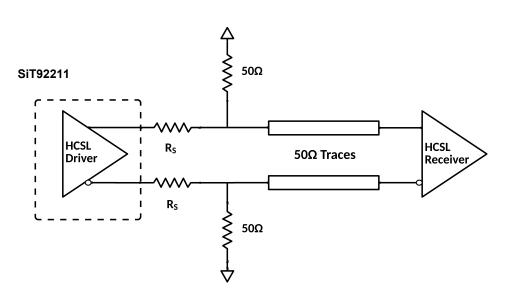


Figure 27 Termination scheme for DC coupled HCSL

LVPECL DC Coupled Output Termination

For DC couple operation, the 50 Ω termination resistors are placed close to the receiver. The termination resistors are biased with a voltage source VTT. Typically,

$$V_{TT} = V_{CCO} - 2V.$$

This termination scheme is shown in Figure 28. Alternatively, the user can also implement a Thevenin equivalent of VTT using a resistor divider.

This scheme and the values of the resistors in the resistor divider are given in Figure 29.



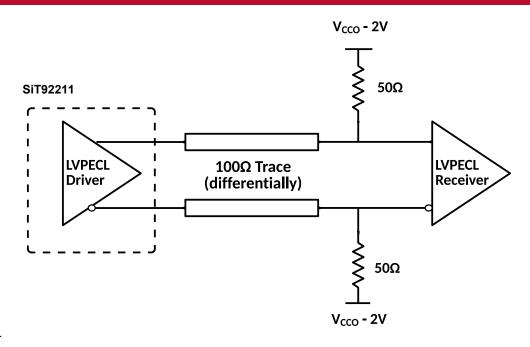


Figure 28 Termination scheme for DC coupled LVPECL

$$\frac{R_{PD} * R_{PU}}{R_{PD} + R_{PU}} = 50\Omega$$

$$\frac{R_{PD}*Vcco}{R_{PD}+R_{PU}}=Vcco-2V$$

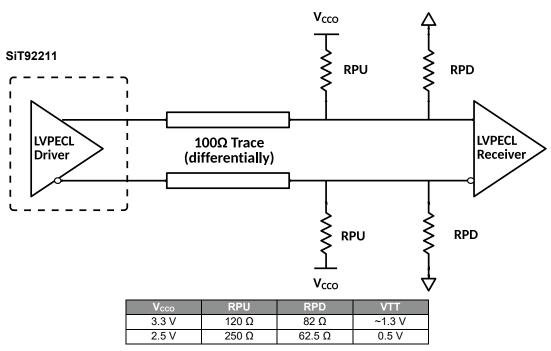


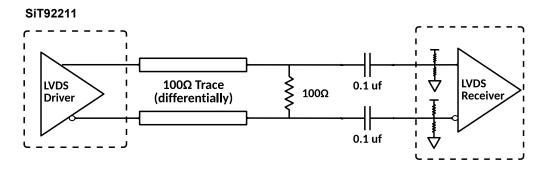
Figure 29 Termination scheme for DC coupled LVPECL, Thevenin equivalent



Termination of Output Drivers (AC coupled) LVDS AC Coupled Output Termination

The load termination resistor should be placed before the AC coupling capacitors. The load termination resistor and the AC coupling capacitors should be placed close to the receiver. The termination scheme is shown in Figure 30. First figure shows SiT92211 output driver configured in LVDS mode. The receiver in this case is shown as LVDS

receiver. The second figure shows SiT92211 output driver configured in LVDS mode and the receiver in this case is shown as CML receiver. As long as the LVDS swing is okay with the recevire the AC coupled output termination is same.



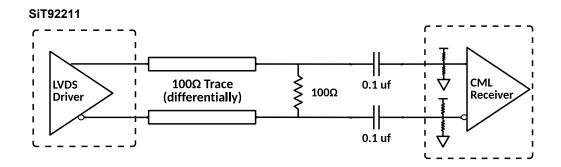


Figure 30 Termination scheme for AC coupled LVDS, driving LVDS receiver and CML receiver

LVPECL AC Coupled Output Termination

The LVPECL should have a DC path to ground. So the user must place a resistance R_T , close to the output driver. The LVPECL AC coupling and Thevenin equivalent VTT termination scheme is shown in Figure 31. SiT92211 swing

reduces by about 20% as the effective load resistor is now the parallel combination of RT at the driver side and 50 Ω at the receiver side.



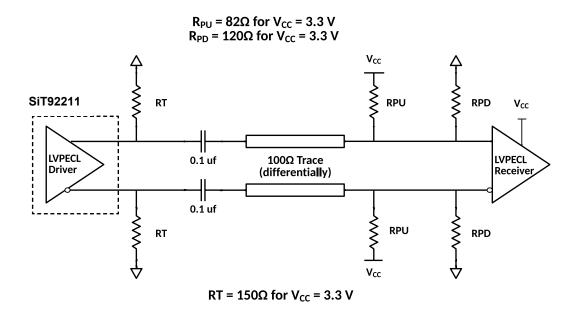


Figure 31 Termination scheme for AC coupled LVPECL, Thevenin Equivalent

The pull up resistance RPU and pull down resistance RPD sets the input common mode voltage for LVPECL receiver. The value of the input common mode voltage can be estimated by the equation given below

estimated by the equation given below
$$V_{ICM} = \frac{Vcc * R_{PD}}{R_{PU+R_{PD}}} = \frac{3.3 * 120}{120 + 82} = 1.961V$$

The LVPECL driver of SiT92211 has resistance RT providing DC path for the output driver current in the LVPECL driver. The effective load impedance at the receiver side is formed by parallel combination of RPU, RPD. The effective termination resistor value is given by the equation below

$$R_{termination} = \frac{R_{PU} * R_{PD}}{R_{PU} + R_{PD}} = \frac{120 * 82}{120 + 82} = 48.7\Omega$$

Termination of Output Drivers in LVPECL Mode, Single Ended, DC coupled

Single ended LVPECL operation is possible. The user can use a balun to convert differential output to single ended output. It is also possible to use the LVPECL driver as one or two separate 700 mV - PP signal. The unused output need to be terminated close to the output driver.

These termination schemes are shown in Figure 32 and Figure 33.

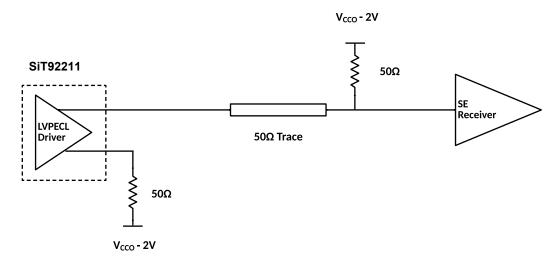


Figure 32 Termination scheme for DC coupled LVPECL, single ended



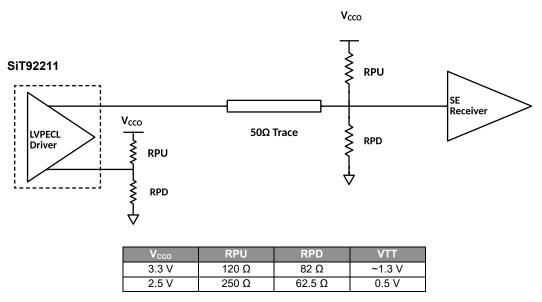
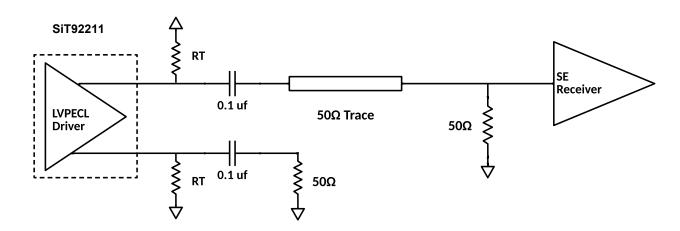


Figure 33 Termination scheme for DC coupled LVPECL, single ended, Thevenin equivalent

Termination of Output Drivers in LVPECL Mode, Single Ended, AC coupled

LVPECL output driver needs a DC path to ground from its output. Therefore 160 Ω (if Vcc = 3.3 V) resistor to ground is connected from the output of the LVPECL driver to

ground. If V_{CC} = 2.5 V, the DC path resistance should be 91 Ω . The 50 Ω load termination resistor must be placed close to input receiver and biased to a suitable voltage.



V _{cco}	RT
3.3 V	160 Ω
2.5 V	91 Ω

Figure 34 Termination scheme for AC coupled LVPECL, single ended



Termination of Output Drivers in AC coupled HCSL mode

Termination resistor is 50 Ω to ground, close to the output driver. A series resistance Rs is sometimes used to limit the overshoot during fast transients. AC coupling capacitor of

0.1 uF is used to couple the output HCSL signal in to the receiver. The same termination can be used for CML receiver.

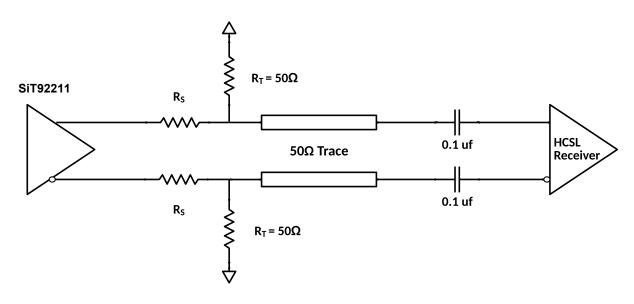


Figure 35 Output driver termination in HCSL AC coupled mode

SiT92211 10 Output, Differential, Ultra Low Jitter Buffer



Thermal Metrics

Table 16 Thermal Metrics

Thermal Metric	SiT92211 QFN 48 pins	Units
θ_{JA} Junction to ambient thermal resistance, flow = 0 m/s	36.3	°C/W
θ_{JA} Junction to ambient thermal resistance, flow = 1 m/s	31.6	°C/W
θ_{JA} Junction to ambient thermal resistance, flow = 2 m/s	30.4	°C/W
$ heta_{JB}$ Junction to board	15.21	°C/W
$ heta_{JC}$ Junction to case	18.90	°C/W
ψ_{JT} Junction to top characterization parameter	0.63	°C/W



HOT Swap Recommendations

Introduction

Hot-swap is a term used to refer to the insertion and removal of a daughter card from a backplane without powering down the system power. With today's high speed data and redundancy requirements, many systems are required to run continuously without being powered down. If special considerations are not taken, the device can be damaged.

Typical Differential Input Clock

For example, Figure 36 shows a typical LVPECL driver and differential input. If the power of the driver (V_{CCO}) is turned on before the input supply (V_{CCI}), there is a possibility that the input current could exceed the limit and damage diode D1.

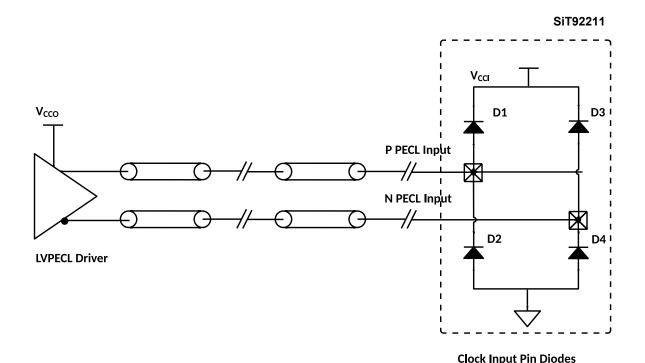


Figure 36 Typical input differential clock

To ensure the input current does not exceed its limit and damage the device, a current limiting resistor can be used. Below are examples of the most common termination topologies using a series current limiting resistor. Though it's not necessary, but if board space allows, some of the

examples have an optional 100 pf capacitor which assists with the integrity of the rise time. It is also recommended that the current limiting resistor be as close to the receiver as possible.

(Pull Up/Pull Down Resistor. Input Termination not shown)



Input Clock Termination with Hot Swap Protection LVPECL Termination Example

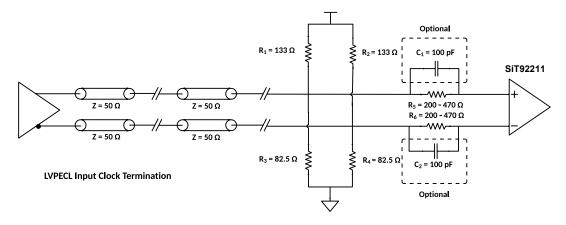


Figure 37 LVEPCL termination with hot swap protection

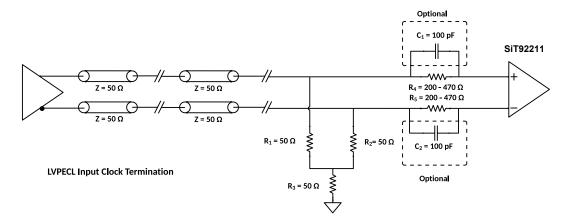


Figure 38 LVPECL termination with hot swap protection

LVDS Input Clock Termination Example

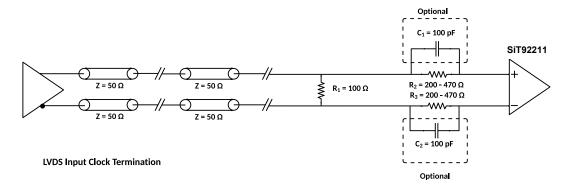


Figure 39 LVDS termination with hot swap protection



HCSL Input Clock Termination Example

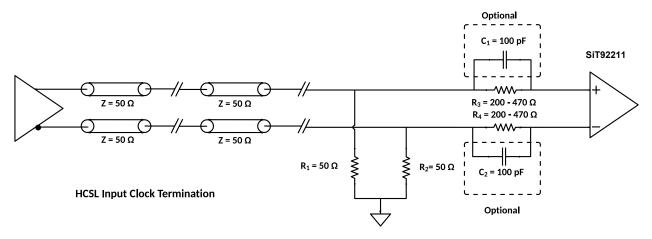


Figure 40 HCSL termination with hot swap protection



LVCMOS Input Clock Termination with Hot Swap Protection

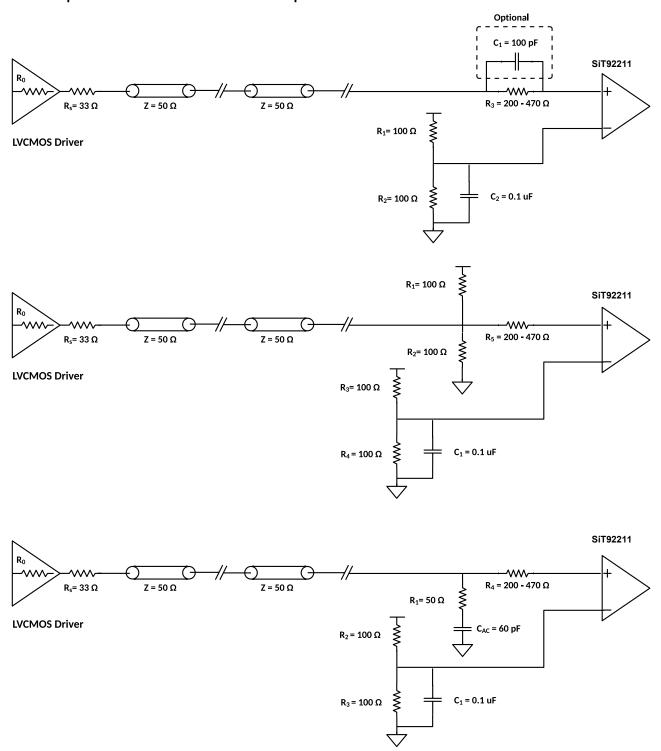
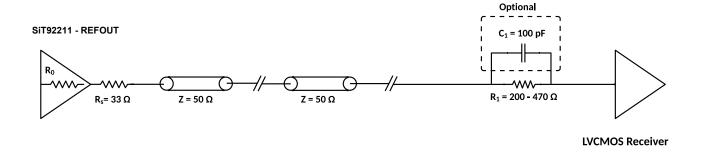
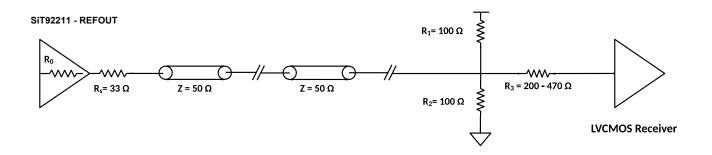


Figure 41 LVCMOS input clock termination with hot swap protection



LVCMOS Output Clock Termination with Hot Swap Protection





SiT92211 - REFOUT

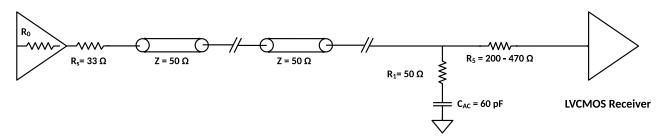


Figure 42 Different types of LVCMOS output clock termination with hot swap protection.



Parameter Measurement Information

Differential Input Level

The parameter definitions related to differential input level is shown in Figure 43.

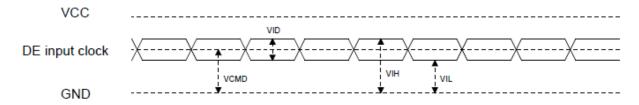


Figure 43 Parameters related to differential input level

Differential Output Level

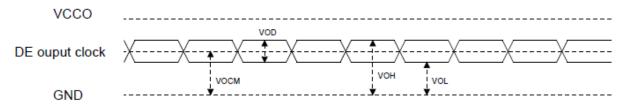


Figure 44 Parameters related to differential output clock levels

Skew and Input to Output Delay

The parameter definitions related to propagation delay and skew are shown in Figure 45.

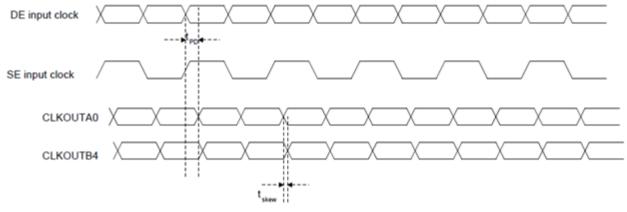


Figure 45 Parameter definitions of propagation delay and skew



Rise and Fall Times

The parameter definitions related to propagation rise and fall times are shown in Figure 46.

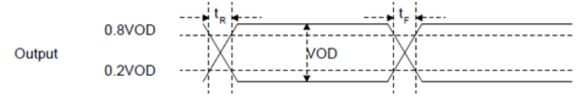


Figure 46 Parameter definitions related to rise and fall times

Isolation

Isolation is a measure of the coupling of clock toggling in unselected input clock path on the output clock. Let us say that CLOCK0 path is selected and there the clock frequency is 156.5 MHz at 0 dBm power. If a clock is toggling in

CLOCK1 path at 156 MHz at 0 dBm, then we there may be a tone at an offset of 0.5 MHz from the carrier, in the output clock. The power of this tone with respect to the carrier is called isolation.

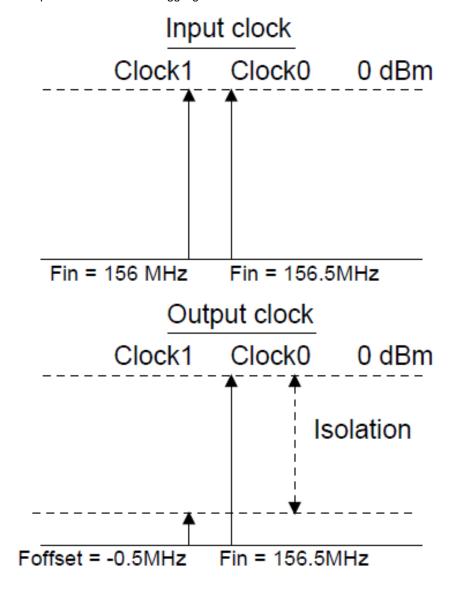


Figure 47 Parameter definition of isolation



Operation in Multiple V_{CCO} Supply Domains

The $V_{\rm CCOA}$ pins, 5 and 8 on the left side are shorted internally. These pins along with ODR CLK_OUTAO to CLK_OUTA4 belong to a single supply domain. The $V_{\rm CCOB}$ pins, 32 and 29 on the right side are shorted internally. These pins along with ODR CLK_OUTBO to CLK_OUTB4 belong

to a single supply domain. These two supply domains are totally independent of each other. Pin 5, 8 can be connected to say 3.3 V while pin 32, 29 can be connected to 2.5 V. In this example, $CLK_{OUT}A0$ to $CLK_{OUT}A4$ will be 3.3 V output driver. $CLK_{OUT}B0$ to $CLK_{OUT}B4$ will be 2.5 V output driver.

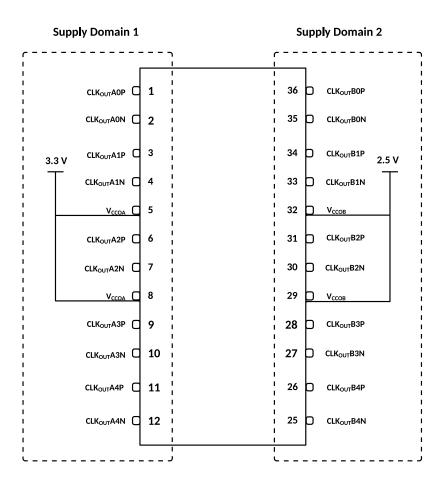
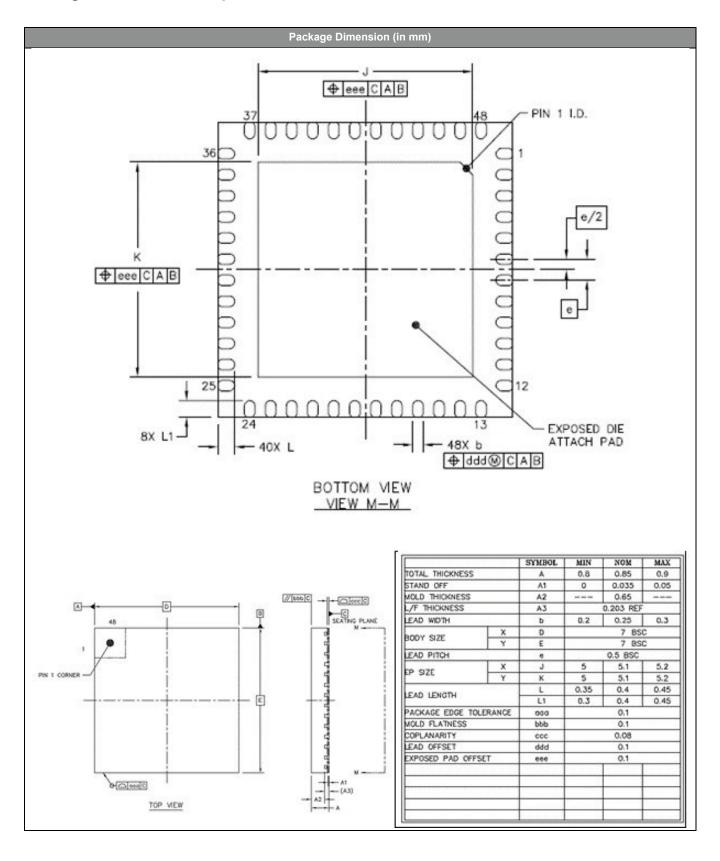


Figure 48: Multi Supply operation of SiT92211



Package Dimensions and patterns





Revision History

Table 17. Revision History

Revisions	Release Date	Change Summary
0.5	Nov 8, 2023	Initial Release

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